SEARCH REQUEST FORM

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| Requester's Full Name: | Number 30 - 1/1/ | Examiner # : | Date: <u>5/2/4</u> |
| Mail Box and Bldg/Room Location | on: 1/2/1/6/2 Re | sults Format Preferred (ci | rcle): PAPER DISK E-MAIL |
| | • | | |
| If more than one search is subs | mitted, please priorit | ize searches in order o | f need. |
| Please provide a detailed statement of th Include the elected species or structures, utility of the invention. Define any term known. Please attach a copy of the cover | e search topic, and describe keywords, synonyms, acre s that may have a special n | e as specifically as possible the onyms, and registry numbers, a meaning. Give examples or rel | e subject matter to be searched. |
| Title of Invention: | 16 12/4 En | Miss Server | |
| Inventors (please provide full names): | Comment of an | iles artes Juli | Conce 14 & Eur Leave |
| Hayan Man K | 1_610 | - · · | \$ |
| Earliest Priority Filing Date: | icenter to 1 | 29 C | |
| *For Sequence Searches Only* Please incli | ude all pertinent information | —— & (parent, child, divisional, or issa | red natent numbers) along with the |
| appropriate serial number. | , | | are process to an area of the control of the contro |
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| TAFF USE ONLY | Type of Search | | where applicable |
| earcher: | | STN | |
| earcher Phone #: | AA Sequence (#) | Dialog | |
| earcher Location: | Structure (#) | Questel/Orbit | |
| ate Searcher Picked Up: | Bibliographic | Dr.Link | |
| | Litigation | Lexis/Nexis | |
| earcher Prep & Review Time: | Fulltext | Sequence Systems | |
| lerical Prep Time: | Patent Family | WWW/Internet | |
| nline Time: | Other | Other (cnecitiv) | |



STIC Search Report

STIC Database Tracking Number: 93401

TO: Camie Thompson Location: CP3 11B28

May 9, 2003

Case Serial Number: 09/868351

From: Kathleen Fuller Location: EIC 1700

CP3/4 3D62

Phone: 308-4290

Kathleen.Fuller@uspto.gov

| Search Notes | | | |
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EIC1700

Search Results Feedback Form (Optional)



The search results generated for your recent request are attached. If you have any questions or comments (compliments or complaints) about the scope or the results of the search, please contact the EIC searcher who conducted the search or contact:

Kathleen Fuller, Team Leader, 308-4290, CP3/4 3D62

| Volu | entary Results Feedback Form | |
|------|---|----------------|
| > | I am an examiner in Workgroup: Example: [1713] | |
| > | Relevant prior art found, search results used as follows: | |
| | 102 rejection | |
| | 103 rejection | |
| | Cited as being of interest. | |
| | Helped examiner better understand the invention. | |
| | Helped examiner better understand the state of the art in their technology. | |
| | Types of relevant prior art found: | |
| | Foreign Patent(s) | • • |
| | Non-Patent Literature (journal articles, conference proceedings, new product announcements etc.) | |
| Þ | Relevant prior art not found: | |
| | Results verified the lack of relevant prior art (helped determine patentability | y). |
| | Search results were not useful in determining patentability or understanding | the invention. |
| Othe | Comments: | |
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THOMPSON 09/868351 Page 1

=> FILE HCAPLUS

FILE 'HCAPLUS' ENTERED AT 12:52:26 ON 09 MAY 2003

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FILE COVERS 1907 - 9 May 2003 VOL 138 ISS 20 FILE LAST UPDATED: 8 May 2003 (20030508/ED)

This file contains CAS Registry Numbers for easy and accurate substance identification.

| | | • |
|------|----------------|--|
| => D | QUE L20 | |
| L2 | 34 | SEA FILE=REGISTRY ABB=ON (12033-89-5/BI OR 12057-24-8/BI OR |
| | | 12063-98-8/BI OR 12137-20-1/BI OR 126213-51-2/BI OR 1303-00-0/B |
| | | I OR 1306-23-6/BI OR 1306-24-7/BI OR 1313-13-9/BI OR 1314-13-2/ |
| | | BI OR 1314-87-0/BI OR 1314-98-3/BI OR 1315-09-9/BI OR 13400-13- |
| | | 0/BI OR 1344-28-1/BI OR 13463-67-7/BI OR 18820-29-6/BI OR |
| | | 21651-19-4/BI OR 24304-00-5/BI OR 37320-90-4/BI OR 409-21-2/BI |
| | | OR 50851-57-5/BI OR 50926-11-9/BI OR 7439-93-2/BI OR 7440-05-3/ |
| | | BI OR 7440-06-4/BI OR 7440-21-3/BI OR 7440-31-5/BI OR 7440-56-4 |
| | | /BI OR 7440-57-5/BI OR 7440-70-2/BI OR 7631-86-9/BI OR |
| | | 7782-49-2/BI OR 7789-24-4/BI) |
| L4 | | SEA FILE=REGISTRY ABB=ON L2 NOT PMS/CI |
| L5 | | SEA FILE=REGISTRY ABB=ON L4 NOT 1/AU, PD, PT |
| L6 | | SEA FILE=REGISTRY ABB=ON L5 AND ITO |
| L7 | 28 | SEA FILE=REGISTRY ABB=ON L5 NOT L6 |
| L8 | 79675 | SEA FILE=HCAPLUS ABB=ON LIGHT?(3A)(EMIS? OR EMIT?) OR EL OR |
| | | ELECTROLUMINES? |
| L9 | | SEA FILE=HCAPLUS ABB=ON OLED |
| L10 | 543 | SEA FILE=HCAPLUS ABB=ON ORG? (5A) (INTERPOS? OR SANDWICH? OR |
| | | BETWEEN?) (3A) ELECTRODE# |
| L11 | | SEA FILE=HCAPLUS ABB=ON (L8 OR L9) AND L10 |
| L12 | | SEA FILE=HCAPLUS ABB=ON L7 |
| L13 | | SEA FILE=HCAPLUS ABB=ON L11 AND L12 |
| L14 | - - | SEA FILE=HCAPLUS ABB=ON L13 AND (DEV/RL OR DEVICE#) |
| L15 | · • | SEA FILE=HCAPLUS ABB=ON L14 AND LAYER? |
| L16 | 3 | SEA FILE=HCAPLUS ABB=ON L15 AND (MULTILAYER? OR PLURAL? (2A) LAY |
| | | ER?) (3A) ELECTRODE? |
| L17 | 1 | SEA FILE=HCAPLUS ABB=ON L15 AND INSULAT? AND CONDUCT? AND |
| | | SEMICONDUCT? |
| L18 | 8 | SEA FILE=HCAPLUS ABB=ON L15 AND (MULTILAYER? OR PLURAL? (2A) LAY |
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| L19 | | SEA FILE=HCAPLUS ABB=ON L15 AND ELECTRODES/IT |
| L20 | 21 | SEA FILE=HCAPLUS ABB=ON (L16 OR L17 OR L18 OR L19) |

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MOST RECENT DERWENT UPDATE: 200329 <200329/DW>
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- >>> NEW WEEKLY SDI FREQUENCY AVAILABLE --> see NEWS <
- >>> SLART (Simultaneous Left and Right Truncation) is now available in the /ABEX field. An additional search field /BIX is also provided which comprises both /BI and /ABEX <<<
- >>> PATENT IMAGES AVAILABLE FOR PRINT AND DISPLAY <<<
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| => D QUE | L31 | |
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| L8 . | 79675 | SEA FILE=HCAPLUS ABB=ON LIGHT?(3A)(EMIS? OR EMIT?) OR EL OR |
| | | ELECTROLUMINES? |
| L9 | 779 | SEA FILE=HCAPLUS ABB=ON OLED |
| L10 | 543 | SEA FILE=HCAPLUS ABB=ON ORG? (5A) (INTERPOS? OR SANDWICH? OR |
| | | BETWEEN?) (3A) ELECTRODE# |
| L21 | 609 | SEA FILE=WPIX ABB=ON (L8 OR L9) AND L10 |
| L23 | 552 | SEA FILE=WPIX ABB=ON L21 AND H05B033?/IC |
| L24 | 79 | SEA FILE=WPIX ABB=ON L23 AND H01L?/IC |
| L25 | 21502 | SEA FILE=WPIX ABB=ON ORG? (3A) LAYER? |
| L26 | 67 | SEA FILE=WPIX ABB=ON L24 AND L25 |
| L27 | 2 | SEA FILE=WPIX ABB=ON L26 AND (MULTILAYER? OR PLURAL? (2A) LAYER? |
| | | |
| L29 | | SEA FILE=WPIX ABB=ON L26 AND MIX? (3A) LAYER? |
| L30 | 13 | SEA FILE=WPIX ABB=ON L26 AND (FLOW? (2A) CURRENT OR CONDUCT? (3A) |
| | | DEFECT? OR RESISTANCE OR CHARGE(2A)CARRIER?) |
| L31 | 16 | SEA FILE=WPIX ABB=ON L27 OR L29 OR L30 |

=> FILE INSPEC

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FILE COVERS 1969 TO DATE.

<<< SIMULTANEOUS LEFT AND RIGHT TRUNCATION AVAILABLE IN
 THE BASIC INDEX >>>

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<>< NEW DISPLAY FORMAT 'SCAN' AVAILABLE NOW >>>
 => D QUE L34
            79675 SEA FILE=HCAPLUS ABB=ON LIGHT?(3A)(EMIS? OR EMIT?) OR EL OR
                  ELECTROLUMINES?
 L9
              779 SEA FILE=HCAPLUS ABB=ON OLED
 L10
              543 SEA FILE=HCAPLUS ABB=ON ORG? (5A) (INTERPOS? OR SANDWICH? OR
                  BETWEEN?) (3A) ELECTRODE#
 <u>L</u>34
               16 SEA FILE=INSPEC ABB=ON (L8 OR L9) AND L10
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 FILE COVERS 1970 TO DATE.
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     THE BASIC INDEX >>>
 <>< NEW DISPLAY FORMAT 'SCAN' AVAILABLE NOW >>>
 => D QUE L35
           79675 SEA FILE=HCAPLUS ABB=ON LIGHT? (3A) (EMIS? OR EMIT?) OR EL OR
T.8
                  ELECTROLUMINES?
T.9
             779 SEA FILE=HCAPLUS ABB=ON OLED
T.10
             543 SEA FILE=HCAPLUS ABB=ON ORG?(5A)(INTERPOS? OR SANDWICH? OR
                 BETWEEN?) (3A) ELECTRODE#
L35
               9 SEA FILE=COMPENDEX ABB=ON (L8 OR L9) AND L10
=> FILE JAPIO
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FILE LAST UPDATED: 4 APR 2003
                                      <20030404/UP>
FILE COVERS APR 1973 TO DECEMBER 26, 2002
<<< GRAPHIC IMAGES AVAILABLE >>>
=> D QUE L33
L8
          79675 SEA FILE=HCAPLUS ABB=ON LIGHT?(3A)(EMIS? OR EMIT?) OR EL OR
                 ELECTROLUMINES?
L9
             779 SEA FILE=HCAPLUS ABB=ON OLED
            543 SEA FILE=HCAPLUS ABB=ON ORG?(5A)(INTERPOS? OR SANDWICH? OR
L10
                 BETWEEN?) (3A) ELECTRODE#
            609 SEA FILE=WPIX ABB=ON (L8 OR L9) AND L10
L21
          552 SEA FILE=WPIX ABB=ON L21 AND H05B033?/IC
79 SEA FILE=WPIX ABB=ON L23 AND H01L?/IC
21502 SEA FILE=WPIX ABB=ON ORG?(3A) LAYER?
L23
L24
L25
L33
             15 SEA FILE=JAPIO ABB=ON L24 AND L25
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=> FILE JICST

FILE 'JICST-EPLUS' ENTERED AT 12:53:40 ON 09 MAY 2003

KATHLEEN FULLER EIC 1700/PARKER LAW 308-4290

THOMPSON 09/868351 Page 3

THOMPSON 09/868351 Page 4

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=> D QUE L36

L8 79675 SEA FILE=HCAPLUS ABB=ON LIGHT?(3A)(EMIS? OR EMIT?) OR EL OR ELECTROLUMINES?

L9 779 SEA FILE=HCAPLUS ABB=ON OLED

L10 543 SEA FILE=HCAPLUS ABB=ON ORG?(5A)(INTERPOS? OR SANDWICH? OR BETWEEN?)(3A)ELECTRODE#

L36 5 SEA FILE=JICST-EPLUS ABB=ON (L8 OR L9) AND L10

=> DUP REM L20 L31 L34 L35 L33 L36

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PROCESSING COMPLETED FOR L31

PROCESSING COMPLETED FOR L34

PROCESSING COMPLETED FOR L35

PROCESSING COMPLETED FOR L33

PROCESSING COMPLETED FOR L36

L37 73 DUP REM L20 L31 L34 L35 L33 L36 (9 DUPLICATES REMOVED)

=> D L37 ALL 1-73

L37 ANSWER 1 OF 73 HCAPLUS COPYRIGHT 2003 ACS

AN 2003:58565 HCAPLUS

DN 138:115173

TI Light emitting device and method of manufacturing the same

IN Yamazaki, Shunpei

PA Japan

SO U.S. Pat. Appl. Publ., 28 pp. CODEN: USXXCO

KATHLEEN FULLER EIC 1700/PARKER LAW 308-4290

12033-89-5, Silicon nitride, uses

RL: DEV (Device component use); USES (Uses) (protective film; light emitting device

having low-resistant electrodes and method of fabrication)

THOMPSON 09/868351 Page 6

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ANSWER 2 OF 73 JICST-EPlus COPYRIGHT 2003 JST
        1030187136 JICST-EPlus
  AN
        Effect of LiF in PVCz Multi Layered Polymer LED's.
   TI
        TANAKA YOSUKE; YOSHIHARA HIROKI; TANAKA SUIKO; KITAGAWA MASAHIKO;
  ΑU
        KOBAYASHI HIROSHI
        KUSANO HIROYUKI
  CS
       Tottori Univ., Fac. of Eng.
       Industrial Technol. Inst., Tottori Prefectural Government, JPN
       Denshi Joho Tsushin Gakkai Gijutsu Kenkyu Hokoku (IEIC Technical Report
  SO
       (Institute of Electronics, Information and Communication Engineers)),
       (2003) vol. 102, no. 601(EID2002 105-119), pp. 45-48. Journal Code: S0532B
       ISSN: 0913-5685
  CY
       Japan
  LΑ
       Japanese
  STA
       New
       We have investigated effect of LiF layer in PVCz based polymer
       light emitting diodes. LiF was inserted between
       organic layer and electrode. Device structures were
       ITO/PVCz:Pe/LiF/Al, ITO/LiF/PVCz:Pe/Al and ITO/LiF/PVCz:Pe/LiF/Al. As a
       result of adjustment for LiF thickness between organic
       layer and electrodes, carrier injection and balance were
       improved. We have described effect of the LiF insertion layer on the
       fundamental EL characteristics of PVCz based PLED devices.
       (author abst.)
 L37 ANSWER 3 OF 73 HCAPLUS COPYRIGHT 2003 ACS
      2002:906774 HCAPLUS
 ΑN
 DN
      138:9496
 TТ
      Electroluminescent device
 IN
      Frey, Gitti; Reynolds, Kieran John
      Cambridge University Technical Services Limited, UK
 PA
 SO
      PCT Int. Appl., 49 pp.
      CODEN: PIXXD2
 DT
      Patent
 LΑ
      English
 IC
      ICM H01L051-20
      73-11 (Optical, Electron, and Mass Spectroscopy and Other Related
      Properties)
      Section cross-reference(s): 76
 FAN.CNT 1
      PATENT NO.
                       KIND DATE
                                            APPLICATION NO. DATE
                             -----
                                             -----
PT
     WO 2002095841
                        A2
                             20021128
                                            WO 2002-GB2306
                                                              20020516
     WO 2002095841
                       A3
                             20030306
         W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN,
             CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH,
             GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR,
             LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, OM, PH,
             PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VN, YU, ZA, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU,
         RW: GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AT, BE, CH,
             CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, TR,
             BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG
PRAI GB 2001-12138
                       Α
                             20010518
     GB 2001-23287
                       Α
                            20010927
    Electroluminescent devices comprising a hole-injecting
AB
    electrode, an electron-injecting electrode and .gtoreq.1
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org. light-emitting layer disposed
  between the hole injecting electrode and the electron
  injecting electrode are described which are provided with a
  layered metal chalcogenide layer disposed between the
  hole-injecting electrode and the light-emitting
  layer, the chalcogen component of the chalcogenide being chosen
  from sulfur, selenium, and tellurium. A method for the prodn. of an
  electroluminescent device having a layered
  metal dichalcogenide layer is also described which entails
  depositing the layered metal dichalcogenide on the hole
  injecting electrode according to the following steps: (a) intercalation of
  lithium atoms into the metal dichalcogenide; (b) addn. of water to the
  resulting intercalated material resulting in an exfoliation reaction so as
  to give single layers of the metal dichalcogenide suspended in
  the water; addn. of a water immiscible solvent to the product of step (b)
  followed by agitation of the resulting mixt. to give a thin film of
 layered metal dichalcogenide at the solvent/water interface; and
  (d) wetting the hole injecting layer supported on a substrate
 and then dipping it into the solvent/water interface produced in step (c)
 above and allowing the thin film of layered metal dichalcogenide
 to spread on the surface of the hole injecting layer.
 org electroluminescent device metal chalcogenide hole
 transporting layer
 Semiconductor device fabrication
    (org. electroluminescent devices with metal
    chalcogenide hole-transporting layers and their fabrication)
 Selenides
 Sulfides, uses
 Tellurides
 RL: CPS (Chemical process); DEV (Device component use); PEP
 (Physical, engineering or chemical process); PYP (Physical process); PROC
 (Process); USES (Uses)
    (org. electroluminescent devices with metal
    chalcogenide hole-transporting layers and their fabrication)
Electroluminescent devices
    (org.; org. electroluminescent devices with metal
   chalcogenide hole-transporting layers and their fabrication)
aluminum alloy, nonbase
barium alloy, nonbase
calcium alloy, nonbase
cerium alloy, nonbase
indium alloy, nonbase
lanthanum alloy, nonbase
lithium alloy, nonbase
magnesium alloy, nonbase
potassium alloy, nonbase
silver alloy, nonbase
sodium alloy, nonbase
strontium alloy, nonbase
tin alloy, nonbase
zinc alloy, nonbase
zirconium alloy, nonbase
RL: CPS (Chemical process); DEV (Device component use); PEP
(Physical, engineering or chemical process); PYP (Physical process); PROC
   (electrodes; org. electroluminescent
  devices with metal chalcogenide hole-transporting
  layers and their fabrication)
```

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1312-43-2, Indium oxide 1314-13-2, Zinc oxide, uses
      Tin oxide
                 50926-11-9, ITO
                                    117944-65-7, Indium zinc oxide
      RL: CPS (Chemical process); DEV (Device component use); PEP
      (Physical, engineering or chemical process); PYP (Physical process); PROC
       (Process); USES (Uses)
          (electrode; org. electroluminescent devices with
         metal chalcogenide hole-transporting layers and their
         fabrication)
 ፐጥ
      210347-52-7, F8BT
                          220797-16-0
                                         316825-94-2
      RL: CPS (Chemical process); DEV (Device component use); PEP
      (Physical, engineering or chemical process); POF (Polymer in formulation);
      PYP (Physical process); PROC (Process); USES (Uses)
         (org. electroluminescent devices with metal
         chalcogenide hole-transporting layers and their fabrication)
      517-51-1, Rubrene 1047-16-1, Quinacridone 1305-78-8, Calcium oxide,
 IΤ
      uses 1309-48-4, Magnesium oxide, uses
                                               1313-59-3, Sodium oxide, uses
      1314-11-0, Strontium oxide, uses 1317-33-5, Molybdenum disulfide, uses
      2085-33-8, Tris(8-hydroxyquinolinato)aluminum 7429-90-5, Aluminium, uses
      7439-91-0, Lanthanum, uses 7439-95-4, Magnesium, uses Potassium, uses 7440-22-4, Silver, uses 7440-23-5, S
                                                                7440-09-7,
                                                 7440-23-5, Sodium, uses
      7440-24-6, Strontium, uses 7440-31-5, Tin, uses
      7440-31-5D, Tin, chalcogenides
                                       7440-32-6D, Titanium,
      chalcogenides
                     7440-33-7D, Tungsten, chalcogenides
                                                            7440-39-3, Barium,
             7440-45-1, Cerium, uses 7440-58-6D, Hafnium, chalcogenides
      7440-62-2D, Vanadium, chalcogenides
                                           7440-66-6, Zinc, uses 7440-67-7,
                        7440-67-7D, Zirconium, chalcogenides 7440-70-2
      Zirconium, uses
      , Calcium, uses
                        7440-74-6, Indium, uses
                                                 12034-77-4, Niobium
     diselenide. 12057-24-8, Lithium oxide, uses 12136-45-7,
      Potassium oxide, uses 12143-72-5, Tantalum disulfide
                                                               18088-11-4,
     Rubidium oxide
                       20281-00-9, Cesium oxide
                                                 62503-57-5, Phenanthrene
                   95270-88-5, PolyFluorene 95270-88-5D, PolyFluorene,
     homopolymer
               96638-49-2, Polyphenylene vinylene
     derivs.
                                                     96638-49-2D, Polyphenylene
     vinylene, derivs. 138184-36-8, MEH-PPV
     RL: CPS (Chemical process); DEV (Device component use); PEP
      (Physical, engineering or chemical process); PYP (Physical process); PROC
      (Process); USES (Uses)
         (org. electroluminescent devices with metal
        chalcogenide hole-transporting layers and their fabrication)
IΤ
     7439-93-2, Lithium, uses
     RL: CPS (Chemical process); DEV (Device component use); PEP
     (Physical, engineering or chemical process); PYP (Physical process); RCT
     (Reactant); PROC (Process); RACT (Reactant or reagent); USES (Uses)
         (org. electroluminescent devices with metal
        chalcogenide hole-transporting layers and their fabrication)
     1303-00-0, Gallium arsenide, uses 1314-98-3, Zinc
ΙT
     sulfide, uses 1315-09-9, Zinc selenide 7440-21-3,
     Silicon, uses 12063-98-8, Gallium phosphide (GaP), uses
     22398-80-7, Indium phosphide, uses
     RL: CPS (Chemical process); DEV (Device component use); PEP
     (Physical, engineering or chemical process); PYP (Physical process); PROC
     (Process); USES (Uses)
        (substrate; org. electroluminescent devices with
        metal chalcogenide hole-transporting layers and their
        fabrication)
L37
    ANSWER 4 OF 73 HCAPLUS COPYRIGHT 2003 ACS
     2002:353954 HCAPLUS
ΑN
DN
     136:361635
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THOMPSON 09/868351 Page 9
 TI
      Light emitting device
 IN
      Seo, Satoshi
 PA
      Japan
 SO
      U.S. Pat. Appl. Publ., 27 pp.
      CODEN: USXXCO
 DT
      Patent
 LΑ
      English
      ICM H01J001-62
 IC
      ICS H01J063-04
 NCL
      313504000
      73-11 (Optical, Electron, and Mass Spectroscopy and Other Related
 CC
      Properties)
      Section cross-reference(s): 76
 FAN.CNT 1
      PATENT NO.
                       KIND DATE
                                            APPLICATION NO. DATE
                             -----
                                            -----
 PΙ
      US 2002053871
                       A1
                             20020509
                                            US 2001-983521
                                                             20011024
      JP 2002203687
                        A2
                             20020719
                                            JP 2001-329147
                                                             20011026
 PRAI JP 2000-327699
                       Α
                             20001026
     Light-emitting devices comprising an org.
     electroluminescent element comprising an anode layer, a
     cathode layer, and an org. compd. layer provided
     between the anode and cathode layers are described in which
      .gtoreq.1 of the anode layer and the cathode layer has
     an oxide film in contact with the org. compd. layer. The org.
     layer may contain or be in contact with a zeolite. Methods for
     fabricating the devices are also described in which the oxide
     film may be formed by anodization processing or sol-gel processing.
     Electronic equipment (org. electroluminescent displays, video
     cameras, digital cameras, image reprodn. app., portable computers,
     personal computers, mobile telephones, and acoustic equipment) employing
     the devices are also described.
     org light emitting device electrode oxide
     layer; zeolite org light emitting
     device electrode
IT
     Anodization
     Semiconductor device fabrication
     Sol-gel processing
        (org. light-emitting devices with oxide
        layers between electrodes and org
        · layers and their fabrication and use)
TΤ
     Zeolites (synthetic), uses
     RL: DEV (Device component use); PEP (Physical, engineering or
     chemical process); PROC (Process); USES (Uses)
        (org. light-emitting devices with oxide
        layers between electrodes and org
        . layers and their fabrication and use)
IT
     Electroluminescent devices
        (org.; org. light-emitting devices with
       oxide layers between electrodes and
       org. layers and their fabrication and use)
IT
    1314-35-8P, Tungsten oxide, uses
                                       1314-61-0P, Tantalum oxide
    13463-67-7P, Titanium oxide, uses
    RL: DEV (Device component use); IMF (Industrial manufacture);
    PEP (Physical, engineering or chemical process); PREP (Preparation); PROC
     (Process); USES (Uses)
       (org. light-emitting devices with oxide
       layers between electrodes and org
```

. layers and their fabrication and use) 4733-39-5, Bathocuproine cuproine 7440-25-7, Tantalum, uses 7440-32-6, 7440-33-7, Tungsten, uses 12686-52-1 50926-11-9, Indium tin oxide 151835-71-1, Poly(2-methoxy-5-octyloxy-p-phenylene RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses) (org. light-emitting devices with oxide layers between electrodes and org . layers and their fabrication and use) 38874-18-9, Penta-n-propoxytantalum IΤ RL: RCT (Reactant); RACT (Reactant or reagent) (org. light-emitting devices with oxide layers between electrodes and org . layers and their fabrication and use) ΙT 50851-57-5 RL: DEV (Device component use); MOA (Modifier or additive use); PEP (Physical, engineering or chemical process); POF (Polymer in formulation); PROC (Process); USES (Uses) (polyethylene dioxythiophene doped with; org. lightemitting devices with oxide layers between electrodes and org. layers and their fabrication and use) 126213-51-2, Poly(3,4-ethylenedioxythiophene) IΤ RL: DEV (Device component use); PEP (Physical, engineering or chemical process); POF (Polymer in formulation); PROC (Process); USES (polystyrene sulfonate-doped; org. light-emitting devices with oxide layers between electrodes and org. layers and their fabrication and use) L37 ANSWER 5 OF 73 INSPEC COPYRIGHT 2003 IEE 2002:7367580 INSPEC DN A2002-20-4265P-004; B2002-10-4260D-018 Organic bistable light-emitting devices. TILiping Ma; Jie Liu; Pyo, S.; Yang Yang (Dept. of Mater. Sci. & Eng., ΑU California Univ., Los Angeles, CA, USA) Applied Physics Letters (21 Jan. 2002) vol.80, no.3, p.362-4. 12 refs. SO Doc. No.: 50003-6951(02)03003-6 Published by: AIP Price: CCCC 0003-6951/2002/80(3)/362(3)/\$19.00 CODEN: APPLAB ISSN: 0003-6951 SICI: 0003-6951(20020121)80:3L.362:OBLE;1-9 DT Journal Practical; Experimental TCCY United States LA English An organic bistable device, with a unique trilayer structure consisting of AΒ organic/metal/organic sandwiched between two outmost metal electrodes, has been invented. [Y. Yang, L. P. Ma, and J. Liu, U.S. Patent Pending, U.S. 01/17206 (2001)]. When the device is suddenly switches from a high-impedance state to a low-impedance state, with a difference in injection current of more than 6 orders of magnitude. When the device is switched to the low-impedance state, it remains in that state even when the power is off. (This is called "nonvolatile" phenomenon in memory devices.) The high-impedance state can be recovered by applying

a reverse bias; therefore, this bistable device is ideal for memory

`THOMPSON 09/868351 Page 11

applications. In order to increase the data read-out rate of this type of memory device, a regular polymer light-emitting diode has been integrated with the organic bistable device, such that it can be read out optically. These features make the organic bistable light -emitting device a promising candidate for several applications, such as digital memories, opto-electronic books, and recordable papers.

- A4265P Optical bistability, multistability and switching; A4280T Optical storage and retrieval; B4260D Light emitting diodes; B4120 Optical storage and retrieval; B4150 Electro-optical devices; B4340P Optical bistability, multistability and switching
- CHARGE INJECTION; ELECTRO-OPTICAL SWITCHES; LIGHT CT EMITTING DIODES; OPTICAL BISTABILITY; OPTICAL STORAGE; ORGANIC
- ST organic bistable light-emitting devices; organic bistable device; trilayer structure; organic/metal/organic sandwiched; metal electrodes; critical state; high-impedance state; low-impedance state; injection current; nonvolatile phenomenon; reverse bias; data read-out rate; polymer light-emitting diode; digital memories; opto-electronic books; recordable papers; 3 V PHP

voltage 3.0E+00 V

ET P; J

L37 ANSWER 6 OF 73 HCAPLUS COPYRIGHT 2003 ACS

2001:449200 HCAPLUS

DN 135:53383

Organic electroluminescent device with improved TΤ long-term stability

Yoon, Jong Geun; Kim, Myung Seop; Oh, Hyoung Yun; Kim, Sung Tae IN PA

Lg Electronics Inc., S. Korea

U.S., 11 pp. CODEN: USXXAM

DT Patent

LΑ English

IC ICM H05B033-12

NCL 428690000

73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Section cross-reference(s): 76, 78

| FAN.CNT 2 | | | , , , , , , | | |
|--|--|------------------------------|--|----------------------------------|----------------------|
| PATE | NT NO. | KIND | DATE | APPLICATION NO. | DATE |
| US 20 PRAI KR 19 KR 19 KR 19 US 19 | 248458 001031380 997-60534 998-18193 998-37215 998-178515 AT 135:53383 | B1 A1 A A A A | 20010619 20011018 19971117 19980520 19980909 19981026 | US 1998-178515 US 2001-848282 | 19981026 20010504 |

AB Org. electroluminescent devices comprising an org. multilayered electroluminescent structure sandwiched between electrodes are described which include .gtoreq.1 layer comprising Li20 along with .gtoreq.1 materials described by the general formula I (R1-4 =independently selected H, C1-5 alkyl or alkoxy groups, aryl, aryloxy, or halo; .gtoreq.1 pair of adjacent substituents of R1-4 may form five- or six-membered conjugated cyclic ring; and A = independently selected H, C1-5 alkyl, or aryls) and/or .gtoreq.1 layer comprising Li20 along with .gtoreq.1 porphyrinic compd. ST

org electroluminescent device lithium oxide laver

IT Metalloporphyrins

Porphyrins

RL: DEV (Device component use); USES (Uses)

(org. electroluminescent devices including lithium oxide-contg. layers)

IT Electroluminescent devices

(org.; org. electroluminescent devices including lithium oxide-contg. layers)

IT 147-14-8, Copper phthalocyanine 2085-33-8, Tris(8hydroxyquinolinato)aluminum 7429-90-5, Aluminum., uses 12057-24-8, Lithium oxide, uses 50926-11-9, ITO 65181-78-4, N,N'-Diphenyl-N,N'-bis(3-methylphenyl)-1,1'-biphenyl-4,4'-diamine RL: DEV (Device component use); USES (Uses) (org. electroluminescent devices including lithium

oxide-contg. layers)

THERE ARE 5 CITED REFERENCES AVAILABLE FOR THIS RECORD RE.CNT 5 RE

- (1) Hung; US 5677572 1997 HCAPLUS
- (2) Matsuura; US 5516577 1996 HCAPLUS
- (3) Murayama; US 5227252 1993 HCAPLUS
- (4) Shi; US 5593788 1997 HCAPLUS
- (5) Tada; US 5616427 1997 HCAPLUS

ANSWER 7 OF 73 HCAPLUS COPYRIGHT 2003 ACS L37

AN 2001:545354 HCAPLUS

DN 135:129364

TΙ Organic electroluminescent devices and manufacture

IN Oka, Tetsuo; Ikeda, Takeshi; Hayashi, Kenji

Toray Industries, Inc., Japan PA

SO Jpn. Kokai Tokkyo Koho, 7 pp. CODEN: JKXXAF

DT Patent

T.A Japanese

IÇ ICM H05B033-04

THOMPSON 09/868351 Page 13 ICS G09F009-00; G09F009-30; H05B033-10; H05B033-14 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties) FAN.CNT 1 PATENT NO. KIND DATE APPLICATION NO. DATE -----ΡI JP 2001203075 A2 20010727 JP 2000-8618 20000118 PRAI JP 2000-8618 20000118 The devices comprise a pair of electrodes interleaving between an org. electroluminescent laminate, where a protective layer comprises a metal and an insulating layer comprises a compd. of the metal layer employed in the protective layer. organoluminescent device protective insulating layer ST IΤ Electrodes Electroluminescent devices Films Glass substrates Humidity (org. electroluminescent devices and manuf.) 147-14-8, Copper phthalocyanine 1344-28-1, Alumina, uses ΙT 2085-33-8, Tris(8-quinolinolato)aluminum 7429-90-5, Aluminum, uses 50926-11-9, ITO 65181-78-4, TPD RL: DEV (Device component use); USES (Uses) (org. electroluminescent devices and manuf.) ANSWER 8 OF 73 INSPEC COPYRIGHT 2003 IEE 2001:6935212 INSPEC DN B2001-07-4260D-013 ΤI Red organic light emitting device made from triphenylene hexaester and perylene tetraester. AU Seguy, I.; Jolinat, P.; Destruel, P.; Farenc, J. (Lab. de Genie Electr., Univ. Paul Sabatier, Toulouse, France); Mamy, R.; Bock, H.; Ip, J.; Nguyen, T.P. Journal of Applied Physics (15 May 2001) vol.89, no.10, p.5442-8. 48 refs. SO Doc. No.: S0021-8979(01)05910-2 Published by: AIP Price: CCCC 0021-8979/2001/89(10)/5442(7)/\$18.00 CODEN: JAPIAU ISSN: 0021-8979 SICI: 0021-8979(20010515)89:10L.5442:OLED;1-G DTJournal ТC Practical; Experimental CY United States LΑ English AΒ Saturated red light emission from organic light emitting diodes is less common than emission in the green or the blue. Most organic red light emitting devices are based on rare earth complexes, mainly europium, which are known to exhibit stability problems. The present article describes new diodes made of indium tin oxide-coated glass/triphenylene hexaether/perylene tetraester/aluminum. The band diagram was determined by ultraviolet photoemission spectroscopy, cyclic voltammetry, scanning tunneling microscopy, and absorbance measurements. The interfaces between electrodes and organic layers were investigated by X-ray photoelectron spectroscopy. The current-voltage and luminance-voltage characteristics are very reproducible from device to device, with an emission peak at 620 nm and a full width at half maximum

of 80 nm, a current rectification ratio of about 30, I V2 at low voltages

and I Lum V6 at higher voltages.

- CC B4260D Light emitting diodes
- CT LIGHT EMITTING DIODES; ORGANIC COMPOUNDS;
 RECTIFICATION; SCANNING TUNNELLING MICROSCOPY; ULTRAVIOLET PHOTOELECTRON SPECTRA; VOLTAMMETRY (CHEMICAL ANALYSIS); X-RAY PHOTOELECTRON SPECTRA
- red organic light emitting device; triphenylene hexaester;
 perylene tetraester; saturated red light emission; organic
 light emitting diodes; rare earth complexes; stability problems;
 indium tin oxide-coated glass; band diagram; ultraviolet photoemission
 spectroscopy; cyclic voltammetry; scanning tunneling microscopy;
 absorbance measurements; X-ray photoelectron spectroscopy;
 luminance-voltage characteristics; current-voltage characteristics;
 emission peak; current rectification ratio; low voltages; ITO; Al; InSnO
- CHI InSnO int, In int, Sn int, O int, InSnO ss, In ss, Sn ss, O ss; Al int, Al
- ET I; Al; In*O*Sn; In sy 3; sy 3; O sy 3; Sn sy 3; InSnO; In cp; cp; Sn cp; O cp; In; Sn; O
- L37 ANSWER 9 OF 73 INSPEC COPYRIGHT 2003 IEE
- AN 2001:6896063 INSPEC DN B2001-05-4260-010
- TI Study on the enhancement of organic semiconducting microcavity light emitting devices.
- AU Wang Wanlu; Liao Kejun (Dept. of Appl. Phys., Chongqing Univ., China)
- Chinese Journal of Quantum Electronics (Feb. 2001) vol.18, no.1, p.66-9.

 Published by: Science Press

Published by: Science Press CODEN: LDXUFI ISSN: 1007-5461 SICI: 1007-5461(200102)18:11 6

SICI: 1007-5461(200102)18:1L.66:SEOS;1-Y

- DT Journal
- TC Experimental
- CY China
- LA Chinese
- AB The microcavity efficiency enhancement of organic electroluminescent devices was investigated. The devices consisted of the hole transporter ladder-type poly(p-phenylene) and the electron transporter 8-hydroxyquinoline aluminum with dye pyrromethene-doping. The microcavity effect could be achieved by adjusting the organic layer thickness between Al and ITO electrodes. The results obtained showed that the microcavity electroluminescence efficiency was greatly enhanced.
- CC B4260 Electroluminescent devices; B4110 Optical materials; B4145 Micro-optical devices and technology
- CT CAVITY RESONATORS; DYES; ELECTROLUMINESCENT DEVICES;
 MICRO-OPTICS; OPTICAL POLYMERS; OPTICAL RESONATORS; ORGANIC SEMICONDUCTORS
- organic semiconducting microcavity light emitting devices;
 microcavity light emitting devices; light emitting devices;
 microcavity; efficient enhancement; organic electroluminescent
 devices; hole transporter; ladder-type poly(p-phenylene); electron
 transporter; 8-hydroxyquinoline aluminum; dye pyrromethene-doping;
 microcavity effect; organic layer thickness; Al electrode; ITO electrode;
 microcavity electroluminescence efficiency;
 electroluminescence efficiency; efficiency enhancement; Al; ITO;
 InSnO
- CHI Al int, Al el; InSnO int, In int, Sn int, O int, InSnO ss, In ss, Sn ss, O ss
- ET Al; In*O*Sn; In sy 3; sy 3; O sy 3; Sn sy 3; InSnO; In cp; cp; Sn cp; O cp; In; Sn; O
- L37 ANSWER 10 OF 73 HCAPLUS COPYRIGHT 2003 ACS DUPLICATE 1

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applicants
 THOMPSON 09/868351 Page 15
      2000:421440 HCAPLUS
 AN
 DN
      133:65837
 ΤI
     Organic light-emitting devices
     Carter, Julian Charles; Burroughes, Jeremy Henley; Heeks, Stephen Karl
 IN
 PA
     Cambridge Display Technology Ltd., UK
 SO
     PCT Int. Appl., 42 pp.
     CODEN: PIXXD2
DT
     Patent
LΑ
     English
IC
     ICM H01L051-20
CC
     73-11 (Optical, Electron, and Mass Spectroscopy and Other Related
     Properties)
     Section cross-reference(s): 76
FAN.CNT 1
     PATENT NO.
                      KIND DATE
                                           APPLICATION NO. DATE
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                                      WO 1999-GB4150 _19991215
PΙ
     WO 2000036662
                     A1
                            20000622
         W: AT, AU, BR, CA, CH, CN, CZ, DE, DK, ES, FI, GB, IL, IN, JP, KR, LU, MX, PT, RU, SE, SG, US
         RW: AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL,
             PT, SE
     EP 1145337
                          20011017
                      A1
                                           EP 1999-961189
                                                            19991215
         R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT,
             IE, FI
     JP 2002532848
                      Т2
                           20021002
                                           JP 2000-588818
                                                            19991215
     CN 1400676
                      Α
                           20030305
                                          CN 2002-142173
                                                           20020829
PRAI GB 1998-27699
                      Α
                           19981216
     GB 1999-7120
                      Α
                           19990326
    WO 1999-GB4150
                      W
                           19991215
AR
    Org. light-emitting devices comprising a
    light-emitting org. layer sandwiched
    between first and second electrodes for injecting charge
    carriers into the org. layer are described which are provided
    with means for limiting the current flow through any conductive
    defect in the light-emissive org. layer.
    The means may be incorporated in the electrodes, and may entail the use of
    materials or electrode structures having resistances which are
    sufficiently high to prevent excessive currents at conductive
    defects in the org. light-emitting layer
```

sufficiently high to prevent excessive currents at conductive defects in the org. light-emitting layer while remaining low enough to avoid significant increases in the drive voltage required to operate the devices. Appropriate materials include mixts. of a semiconductor material with an insulating material, mixts. of a semiconductor material with a conductive material, and mixts. of an insulating material with a conductive material. Appropriate structures include multilayered structures including .gtoreq.1 layer having a high resistivity. The electrodes may also be constructed as a series of subelectrodes connected by fusible links. Methods of forming the electrodes are also described. PEDT-PSS.

org electroluminescent device conductive defect isolating electrode

IT Electric contacts

Electrodes

Electrodes
Electroluminescent devices
Electroluminescent devices
Semiconductor device fabrication
(org. light-emitting devices with
electrode structures for isolating conductive defects)

```
409-21-2, Silicon carbide, uses 1303-00-0, Gallium
      arsenide, uses 1306-23-6, Cadmium sulfide, uses
      1306-24-7, Cadmium selenide, uses 1313-13-9, Manganese
      dioxide, uses 1314-13-2, Zinc oxide (ZnO), uses
      1314-87-0, Lead sulfide (PbS) 1314-98-3, Zinc sulfide,
      uses 1315-09-9, Zinc selenide 1344-28-1, Alumina, uses
      7439-93-2, Lithium, uses
                                7440-05-3, Palladium, uses
                                                               7440-06-4,
      Platinum, uses 7440-21-3, Silicon, uses 7440-31-5,
      Tin, uses 7440-56-4, Germanium, uses
                                            7440-57-5, Gold, uses
      7440-70-2, Calcium, uses 7631-86-9, Silica, uses
      7782-49-2, Selenium, uses 7789-24-4, Lithium fluoride
      (LiF), uses 12033-89-5, Silicon nitride, uses 12057-24-8
      , Lithium oxide, uses 12063-98-8, Gallium phosphide (GaP), uses
      12137-20-1, Titanium monoxide 13400-13-0, Cesium
      fluoride (CsF) 13463-67-7, Titanium dioxide, uses
      18820-29-6, Manganese sulfide 21651-19-4, Tin monoxide
      24304-00-5, Aluminum nitride (AlN) 37320-90-4, Manganese
                 50926-11-9, Indium tin oxide
      RL: DEV (Device component use); USES (Uses)
         (org. light-emitting devices with
         electrode structures for isolating conductive defects)
 IT
      50851-57-5
      RL: DEV (Device component use); MOA (Modifier or additive use);
      USES (Uses)
         (polyethylene dioxythiophene doped with; org. light-
         emitting devices with electrode structures for
         isolating conductive defects)
 IT
      126213-51-2
      RL: DEV (Device component use); USES (Uses)
         (polystyrene sulfonate-doped; org. light-emitting
        devices with electrode structures for isolating
         conductive defects)
              THERE ARE 8 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT 8
RF.
 (1) Cambridge Display Tech; EP 0901176 A 1999 HCAPLUS
 (2) Eastman Kodak Co; EP 0903964 A 1999 HCAPLUS
(3) Gyotoku, A; PROCEEDINGS OF THE 1997 INTERNATIONAL CONFERENCE ON
    ELECTROLUMINESCENCE OF MOLECULAR MATERIALS AND RELATED PHENOMENA 1997,
    V91(1-3), P73
(4) Gyotoku, A; Synth Met; Synthetic Metals 1997, P73
(5) Haight, R; US 5739545 A 1998 HCAPLUS
(6) Jabbour, G; APPLIED PHYSICS LETTERS 1998, V73(9), P1185 HCAPLUS
(7) Kitabayashi, M; US 4647813 A 1987
(8) Uniax Corp; WO 9732452 A 1997 HCAPLUS
T.37
     ANSWER 11 OF 73 HCAPLUS COPYRIGHT 2003 ACS
                                                        DUPLICATE 2
AN
     2000:421439 HCAPLUS
DN
     133:65836
TΙ
     Organic light-emitting devices
     Heeks, Stephen Karl; Burroughes, Jeremy Henley; Carter, Julian Charles
IN
PA
     Cambridge Display Technology Ltd., UK
     PCT Int. Appl., 18 pp.
SO
     CODEN: PIXXD2
DT
     Patent
LA
     English
IC
     ICM H01L051-20
     73-11 (Optical, Electron, and Mass Spectroscopy and Other Related
CC
     Properties)
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Section cross-reference(s): 76
 FAN.CNT 1
      PATENT NO.
                       KIND DATE
                                           APPLICATION NO. DATE
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                                            -----
 ΡI
      WO 2000036661
                       A1 20000622
                                          WO 1999-GB4144
                                                            19991214
          W: AT, AU, BR, CA, CH, CN, CZ, DE, DK, ES, FI, GB, IL, IN, JP, KR,
              LU, MX, PT, RU, SE, US
          RW: AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL,
              PT, SE
      EP 1145336
                        A1
                             20011017
                                           EP 1999-959554
                                                             19991214
             AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT,
              IE, FI
      JP 2002532847
                        T2
                             20021002
                                           JP 2000-588817
                                                            19991214
 PRAI GB 1998-27827
                       Α
                             19981217
      GB 1999-22723
                       Α
                             19990924
      WO 1999-GB4144
                       W
                            19991214
 AB
      Org. light-emitting device comprising a
      layer of light-emissive org.
     material interposed between a first electrode
     and a second electrode, at least one of the first and second electrodes
     comprising one or more electrode layers on the layer
     of light-emissive org. material for injecting charge
     carriers into the light-emissive org. material,
     wherein the org. light-emitting device
     further comprises a layer of dielec. material on the surface of
     the outermost electrode layer remote from the layer of
     light-emissive org. material. Org. light-
     emitting devices comprising an org. emitting
     structure sandwiched between first and second electrodes
     are described which are provided with a capping layer formed of
     a dielec. or other inert material on the surface of the outermost
     electrode (e.g., the cathode); .gtoreq.1 gettering layers may be
     provided between the capping layer and the electrode to absorb
     moisture and O2. The capping layer may have a
     multilayer structure including addnl. inert barrier layers
     (e.g., an Al layer underlying an upper AlN layer).
     Methods for fabricating the devices including the deposition of
     the inert barrier layers using a vacuum evapn. technique are
     also described.
     org electroluminescent device electrode protective cap
ST
ΙT
     Electroluminescent devices
       Electroluminescent devices
     Semiconductor device fabrication
        (org. light-emitting devices with
        protective capping layers overlying their electrode
        structures)
     1304-28-5, Barium oxide (BaO), uses 7439-93-2, Lithium, uses
ΙT
    7440-39-3, Barium, uses 7440-46-2, Cesium, uses 7440-70-2,
     Calcium, uses 12798-95-7
    RL: DEV (Device component use); USES (Uses)
        (gettering layer; org. light-emitting
        devices with protective capping layers overlying
        their electrode structures)
IT
    1344-28-1, Alumina, uses 7429-90-5, Aluminum, uses
    7631-86-9, Silica, uses 12033-89-5, Silicon nitride,
    uses 24304-00-5, Aluminum nitride 96638-49-2, Polyphenylene
    vinylene 113443-18-8, Silicon monoxide
                                               138184-36-8, MEH-PPV
    RL: DEV (Device component use); USES (Uses)
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(org. light-emitting devices with
          protective capping layers overlying their electrode
          structures)
  RE.CNT
               THERE ARE 7 CITED REFERENCES AVAILABLE FOR THIS RECORD
  (1) Anon; PATENT ABSTRACTS OF JAPAN 1995, V1995(10)
  (2) Cambridge Display Tech; WO 9810473 A 1998 HCAPLUS
  (3) Fed Corp; WO 9859528 A 1998 HCAPLUS
  (4) Fed Corp; WO 9902277 A 1999 HCAPLUS
  (5) Idemitsu Kosan Co Ltd; JP 07169567 A 1995
  (6) Motorola Inc; EP 0741419 A 1996 HCAPLUS
  (7) Motorola Inc; EP 0777280 A 1997 HCAPLUS
 L37 ANSWER 12 OF 73 HCAPLUS COPYRIGHT 2003 ACS
      2000:590056 HCAPLUS
 ΑN
 DN
      133:185328
 ΤI
      Organic EL light emitting element with
      light emitting layers and intermediate
      conductive layer
 IN
      Tanaka, Shosaku; Hosakawa, Chishio
 PA
      Idemitsu Kosan Co., Ltd., Japan
 SO
      U.S., 15 pp.
      CODEN: USXXAM
 DТ
      Patent
 LΑ
    English
 IC'
      ICM H01J063-04
 NCL 313506000
      73-11 (Optical, Electron, and Mass Spectroscopy and Other Related
      Properties)
      Section cross-reference(s): 74, 76
 FAN.CNT 1
      PATENT NO.
                      KIND DATE
                                           APPLICATION NO.
                                                            DATE
      ______
                      ----
                                           -----
     US 6107734
                     Α
                            20000822
                                           US 1998-161503
                                                            19980928
 PRAI US 1998-161503
                            19980928
     Org. electroluminescent elements are described which comprise a
     transparent electrode; an electrode arranged opposite the transparent
     electrode; an intermediate conductive layer; and a
     plurality of org. light emitting
     layers arranged between the electrodes in a
     manner to sandwich the intermediate conductive layer in an
     intermediate position. Devices in which the elements are
     arranged as pixels in 1- or 2-dimensional arrays are also described.
     intermediate conductive layers allow individual elements to be
     connected in series with one another.
     org electroluminescent device intermediate conductive
ST
     layer series connection
TT
     Electroluminescent devices
        (org. electroluminescent elements with intermediate
        conductive layers for series connection)
     2085-33-8 7439-93-2, Lithium, uses 50926-11-9, Indium tin
IT
            117944-65-7, Indium zinc oxide 123847-85-8, N,N'-Bis(1-naphthy1)-
     N,N'-diphenyl-4,4'-benzidine 124729-98-2, 4,4',4''-Tri{N-(methylphenyl)-
     N-phenyl amino}triphenylamine
                                   288584-84-9, V 259
     RL: DEV (Device component use); USES (Uses)
        (org. electroluminescent elements with intermediate
        conductive layers for series connection)
RE.CNT 1
             THERE ARE 1 CITED REFERENCES AVAILABLE FOR THIS RECORD
```

displays

Tamura, Shinichiro Sony Corp., Japan

IN

PA

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THOMPSON 09/868351 Page 20
       Jpn. Kokai Tokkyo Koho, 13 pp.
  SO
       CODEN: JKXXAF
  DT
       Patent
  LΑ
       Japanese
  IC
       ICM H05B033-22
       ICS H05B033-14; H05B033-26
       74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other
       Reprographic Processes)
       Section cross-reference(s): 73
  FAN.CNT 1
      PATENT NO.
                       KIND DATE
                                            APPLICATION NO. DATE
       ------
                             -----
                                            -----
      JP 2000040591
 PΙ
                       A2
                             20000208
                                            JP 1998-205516
                                                             19980721
      US 6410168
                       В1
                             20020625
                                            US 1999-352751
                                                             19990714
      KR 2000011851
                       Α
                             20000225
                                           KR 1999-29439
                                                             19990721
 PRAI JP 1998-205516
                       Α
                             19980721
      The devices have org. electroluminescent
      layers between 1st electrode layers
      and 2nd electrode layers with UV reflectivity .ltoreq.50%.
      devices may have low-reflection layers or elec.
      conducting layers as electrodes on the 2nd electrode
      layers. Mirror reflection of the 2nd electrode layers
      is decreased.
      electroluminescent display metal electrode reflection
 ST
      prevention; antireflective film electroluminescent display
      contrast improvement; elec conducting layer
      electroluminescent display contrast improvement
 TΤ
      Carbon black, uses
      RL: DEV (Device component use); MOA (Modifier or additive use);
      USES (Uses)
         (colorants, low-reflection layers; prevention of reflection
         of metal electrodes in org. electroluminescent
         devices for high-contrast displays)
 IT
     Polyacetylenes, uses
      Polyanilines
     RL: DEV (Device component use); USES (Uses)
         (elec. conducting layers; prevention of reflection of metal
        electrodes in org. electroluminescent devices
        for high-contrast displays)
TΤ
     Films
     Films
        (elec. conductive; prevention of reflection of metal electrodes
        in org. electroluminescent devices for
        high-contrast displays)
IT
     Electric conductors
     Electric conductors
        (films; prevention of reflection of metal electrodes in org.
        electroluminescent devices for high-contrast
        displays)
IT
     Polymers, uses
     RL: DEV (Device component use); USES (Uses)
        (polythiophenes, elec. conducting layers; prevention of
        reflection of metal electrodes in org.
       electroluminescent devices for high-contrast
       displays)
    Antireflective films
IΤ
      Electroluminescent devices
        (prevention of reflection of metal electrodes in org.
```

```
electroluminescent devices for high-contrast
          displays)
  ΙT
       9004-34-6, Cellulose, uses
       RL: DEV (Device component use); USES (Uses)
          (binders of low-reflection layers; prevention of reflection
          of metal electrodes in org. electroluminescent
          devices for high-contrast displays)
       13007-86-8, Aniline black
       RL: DEV (Device component use); MOA (Modifier or additive use);
       USES (Uses)
          (colorants, low-reflection layers; prevention of reflection
          of metal electrodes in org. electroluminescent
          devices for high-contrast displays)
 IT
       409-21-2, Silicon carbide, uses
                                        7439-89-6, Iron, uses
       7439-92-1, Lead, uses
                              7439-98-7, Molybdenum, uses 7440-02-0, Nickel,
             7440-06-4, Platinum, uses 7440-24-6, Strontium, uses -5, Tin, uses 7440-32-6, Titanium, uses 7440-33-7,
       7440-31-5, Tin, uses
      Tungsten, uses
                      7440-36-0, Antimony, uses 7440-41-7, Beryllium, uses
      7440-47-3, Chromium, uses 7440-50-8, Copper, uses
                                                            117944-65-7, Indium
      zinc oxide
      RL: DEV (Device component use); USES (Uses)
         (elec. conducting layers; prevention of reflection of metal
         electrodes in org. electroluminescent devices
         for high-contrast displays)
      1332-29-2, Tin oxide
 IΤ
                             7429-90-5, Aluminum, uses 7439-93-2,
      Lithium, uses
                      7439-95-4, Magnesium, uses 7440-70-2, Calcium,
      uses
             12798-95-7
                          50926-11-9, ITO
                                            257906-19-7, Magnesium 97, silver
      3.2
      RL: DEV (Device component use); USES (Uses)
         (electrodes; prevention of reflection of metal
         electrodes in org. electroluminescent devices
         for high-contrast displays)
      128-69-8, Perylenetetracarboxylic anhydride
                                                    147-14-8, Copper
                       13775-53-6, Sodium fluoroaluminate (Na3AlF6)
      phthalocyanine
     RL: DEV (Device component use); USES (Uses)
         (low-reflection layers; prevention of reflection of metal
        electrodes in org. electroluminescent devices
        for high-contrast displays)
ΙT
     12597-68-1, Stainless steel, uses
     RL: DEV (Device component use); USES (Uses)
        (sealing containers; prevention of reflection of metal
        electrodes in org. electroluminescent devices
        for high-contrast displays)
L37 ANSWER 15 OF 73 WPIX
                              (C) 2003 THOMSON DERWENT
     2001-090954 [10]
AN
                       WPIX
DNN N2001-068949
                        DNC C2001-026648
     Statistical copolymer systems useful as e.g. electrically conducting
ΤI
     material in electrophotography comprises covalently linked polymer chains
     bearing an electrically active organic substitution. .
DC
     A14 A85 L03 S06 U11 U12 X12 X15
     FEAST, W J; PEACE, R J; SAGE, I C; WOOD, E L
IN
     (QINE-N) QINETIQ LTD; (MINA) UK SEC FOR DEFENCE
PΑ
CYC 22
     WO 2000069931 Al 20001123 (200110)* EN
PΙ
                                               42p
                                                      C08F212-14
        RW: AT BE CH CY DE DK ES FI FR GB GR IE IT LU MC NL PT SE
        W: GB JP KR US
     GB 2363384 A 20011219 (200203)
                                                      C08F212-14
```

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Al 20020306 (200224) EN
      EP 1183287
                                                     C08F212-14
          R: AT BE CH CY DE DK ES FI FR GB GR IE IT LI LU MC NL PT SE
      KR 2001114262 A 20011231 (200240)
                                                      C08F212-14
      JP 2002544345 W 20021224 (200313)
                                               50p
                                                      C08F212-32
      WO 2000069931 A1 WO 2000-GB1636 20000427; GB 2363384 A WO 2000-GB1636
      20000427, GB 2001-24379 20011011; EP 1183287 A1 EP 2000-927461 20000427,
      WO 2000-GB1636 20000427; KR 2001114262 A KR 2001-714415 20011112; JP
      2002544345 W JP 2000-618346 20000427, WO 2000-GB1636 20000427
      GB 2363384 A Based on WO 200069931; EP 1183287 A1 Based on WO 200069931;
      JP 2002544345 W Based on WO 200069931
 PRAI GB 1999-10963
                       19990512
      ICM C08F212-14; C08F212-32
          C08F226-00; H01B001-12; H01L051-00; H05B033-12;
           H05B033-14; H05B033-22
      WO 200069931 A UPAB: 20010220
 AB
     NOVELTY - Statistical copolymer systems comprising covalently linked
     polymer chains bearing an electrically active organic substitution are
           DETAILED DESCRIPTION - Statistical copolymer systems comprising
      covalently linked polymer chains bearing the electrically active organic
     substitution of formula: ((-C(A)(X)CH2)m-(CH2-C(B)(Z)-)j)Q(I) is new.
      m = 0.1 - 0.9;
     j = 1 - m;
          Q = 10 - 50,000;
          A and B = hole and electron transporting groups statistically
      distributed along the polymer chain;
          X and Z = H, CN, F, Cl, Br, CO2CH3.
          An INDEPENDENT CLAIM is also included for an organic semiconductor
     device/photorefractive device comprising a substrate bearing an
     organic layer sandwiched between
     electrode structures. The organic layer
     comprises the statistical copolymer.
          USE - As electrically conducting and electronically active materials
     useful as sensitive layers in electrophotography, photocopying and
     printing applications and in semi-conductor devices or photosensitive
     devices e.g. photodiodes, photovoltaic cells or photoreflective layers.
          ADVANTAGE - (I) has a high charge transport characteristics,
     combination of electronic work function which is one factor determining
     the electric potential required to inject charge in to the polymer from a
     metallic or semiconducting electrode, charge carrier
     mobility, the ability to afford control over emission wavelength and
     bandwidth, ease of synthesis from readily available and in expensive
     starting materials, solubility, film forming ability and high physical and
     chemical stability of deposited films of the polymer in storage and in
     operating devices. The polymers unexpectedly show excellent solubility in
     common solvents and may be processed into uniform films suitable for
     device fabrication simply by spin coating from solution and therefore
     satisfy the requirements for fabrication of organic semiconductor devices
     in large areas by inexpensive and rapid processing methods.
     Dwg.0/15
     CPI EPI
FS
FΑ
     AB; GI
     CPI: A12-E07C; A12-L05D; A12-W07; L03-A02D; L03-C02C; L04-A04; L04-E05
MC
     EPI: S06-A01A1; U11-A01F; U12-A01A1X; U12-A02A2X; U12-A02B5X; U12-B03C;
          X12-D01C; X12-D01C1; X15-A02A
L37
    ANSWER 16 OF 73 WPIX
                             (C) 2003 THOMSON DERWENT
     2001-015605 [02]
AN
                       WPIX
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DNN N2001-011883
                        DNC C2001-004089
     Organic electroluminescent device, e.g. light-
     emitting diode useful for flat panel display, has charge
     carrier injection layer containing complex fluoride of two
     different metals.
DC
     E12 E14 L03 U11 U12
IN
     KANITZ, A; STOESSEL, M
PA
     (SIEI) OSRAM OPTO SEMICONDUCTORS GMBH & CO OHG; (SIEI) SIEMENS AG
CYC 25
     WO 2000057499 A1 20000928 (200102)* DE
PΤ
                                              28p
                                                     H01L051-20
                                                                      <--
        RW: AT BE CH CY DE DK ES FI FR GB GR IE IT LU MC NL PT SE
         W: CA CN JP KR US
                   A1 20020116 (200207) DE
                                                     H01L051-20
         R: AT BE CH CY DE DK ES FI FR GB GR IE IT LI LU MC NL PT SE
     KR 2001109321 A 20011208 (200237)
                                                     H05B033-26
                                                                     <--
     CN 1344428
                   Α
                      20020410 (200249)
                                                     H01L051-20
                                                                     <--
     JP 2002540566 W
                      20021126 (200307)
                                              23p
                                                     H05B033-22
                                                                     <--
     TW 488185
                 A 20020521 (200320)
                                                     H05B033-00
                                                                     <--
ADT WO 2000057499 A1 WO 2000-DE783 20000313; EP 1171921 A1 EP 2000-920388
     20000313, WO 2000-DE783 20000313; KR 2001109321 A KR 2001-712135 20010924;
     CN 1344428 A CN 2000-805374 20000313; JP 2002540566 W JP 2000-607288
     20000313, WO 2000-DE783 20000313; TW 488185 A TW 2000-105059 20000320
FDT EP 1171921 A1 Based on WO 200057499; JP 2002540566 W Based on WO 200057499
PRAI DE 1999-19913350 19990324
    ICM H01L051-20; H05B033-00; H05B033-22;
          H05B033-26
     ICS H05B033-04; H05B033-14
    WO 200057499 A UPAB: 20010110
AΒ
    NOVELTY - Organic electroluminescent device, especially organic
    light-emitting diode, has a transparent bottom electrode
    on a substrate, a top metal electrode, organic functional
    layer(s) and a charge carrier injection layer
    containing a complex fluoride of 2 different metals comprising (a)
    lithium, sodium, potassium, magnesium or calcium and (b) magnesium,
    aluminum, calcium, zinc, silver, antimony, barium, samarium or ytterbium.
         DETAILED DESCRIPTION - Organic electroluminescent device (
    OLED), especially organic light-emitting
    diode, has a transparent bottom electrode on a substrate, a top electrode
    of metal inert towards oxygen and humidity, organic functional
    layer(s) between the electrodes and a
    charge carrier injection layer containing a complex
    fluoride of 2 different metals of composition (I).
         (Me1) (Me2) Fm+n
         m, n = integers corresponding to the valencies of Mel and Me2;
         Me1 = lithium (Li), sodium (Na), potassium (K), magnesium (Mg) or
    calcium (Ca);
         Me2 = Mg, aluminum (Al), Ca, zinc (Zn), silver (Ag), antimony (Sb),
    barium (Ba), samarium (Sm) or ytterbium (Yb), provided
    Me1 not = Me2.
         USE - The organic light-emitting diodes (OLEDs)
    are useful for flat panel displays, e.g. for mobile and portable
    electronic equipment.
         ADVANTAGE - The complex fluoride layer makes hermetic sealing of the
    top electrode unnecessary and also extends the range of materials that can
    be used on the cathode side.
         DESCRIPTION OF DRAWING(S) - The drawing shows the OLED
   display described in the example.
         Glass substrate 21
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THOMPSON 09/868351 Page 24
       ITO film 22
       m-TPD film 23
       Alq3 film 24
       LiAlF4 film 25
            Top electrode of aluminum 26
       Dwg.2/5
  FS
       CPI EPI
  FΑ
       AB; GI; DCN
       CPI: E05-B03; E10-B01A4; E31-M; E33-B; E33-G; E34; E35-B; E35-C; L03-G05;
  MC
            L04-E03; L04-E03A
       EPI: U11-C18B4; U12-A01A1; U12-E02
 L37
      ANSWER 17 OF 73 WPIX
                               (C) 2003 THOMSON DERWENT
 AN
       2000-602165 [57]
                          WPTX
 DNN N2000-445532
                          DNC C2000-180267
 ΤI
      Organic electro-luminescent device includes light
      emitting layer with high resistance conductive path to
      transport holes and block electrons.
 DC
      L03 U14 X26
. IN
      ARAI, M
      (DENK) TDK CORP
 PA
 CYC 23
 PΙ
      WO 2000056123 A1 20000921 (200057)* JA
                                                50p
                                                       H05B033-22
         RW: AT BE CH CY DE DK ES FI FR GB GR IE IT LU MC NL PT SE
          W: CN KR
      JP 2000268973 A 20000929 (200063)
                                                16p
                                                       H05B033-22
      US 6249085
                    B1 20010619 (200137)
                                                       H01L035-24
                                                                       <--
      EP 1117277
                    A1 20010718 (200142)
                                                       H05B033-22
                                                                       <--
          R: DE FR GB IT NL
      CN 1297671
                    A 20010530 (200156)
                                                       H05B033-22
                                                                       <--
      TW 439391
                    A 20010607 (200175)
                                                       H05B033-22
                                                                       <--
      KR 2001071252 A 20010728 (200208)
                                                       H05B033-22
     WO 2000056123 A1 WO 1999-JP3393 19990625; JP 2000268973 A JP 1999-71784
      19990317; US 6249085 B1 US 1999-339881 19990625; EP 1117277 A1 EP
      1999-926811 19990625, WO 1999-JP3393 19990625; CN 1297671 A CN 1999-805179
     19990625; TW 439391 A TW 1999-110779 19990625; KR 2001071252 A KR
      2000-712707 20001113
FDT EP 1117277 A1 Based on WO 200056123
 PRAI JP 1999-71784
                       19990317
IC
     ICM H01L035-24; H05B033-22
          C09K011-06; H05B033-14
     ICS
AΒ
     WO 200056123 A UPAB: 20001109
     NOVELTY - An organic EL device comprises a hole injection
     electrode (2) and an electron injection electrode (6) with an
     organic layer (4) between the
     electrodes (2,6). A light emitting layer
     contains a conjugated polymer, and an inorganic hole injection
     layer (3) between the organic layer (4) and
     the hole injection electrode (2). A conductive path blocks electrons and
     transports holes, and has a high resistance.
          USE - Electro-luminescent device.
          ADVANTAGE - The organic electro-luminescent device has high
     efficiency, long life, and can be produced at low cost
     Dwg.1/4
FS
     CPI EPI
FΑ
     AB; GI
MC
     CPI: L03-C
     EPI: U14-J02; X26-J
```

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ANSWER 18 OF 73 WPIX
                              (C) 2003 THOMSON DERWENT
      2000-595714 [57]
 AN
                         WPIX
 DNN N2000-441261
                         DNC C2000-178101
     Organic electroluminescent device having inorganic/organic
     junction structure has high resistance inorganic hole-injecting
     layer between hole-injecting electrode and light-
     emitting organic layer.
DC
     L03 U14 X26
ΙN
     ARAI, M; KOBORI, I; MITSUHASHI, E
PA
     (DENK) TDK CO LTD; (DENK) TDK CORP
CYC 29
PΙ
     EP 1041654
                   A1 20001004 (200057)* EN
                                               16p
                                                     H01L051-20
         R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT
            RO SE SI
     JP 2000294376 A 20001020 (200059)
                                              13p
                                                     H05B033-22
                                                                      <--
     CN 1269690 A 20001011 (200103)
                                                     H05B033-00
                                                                      <--
     KR 2001014660 A 20010226 (200156)
                                                     H05B033-22
                                                                      <--
     TW 443075
                A 20010623 (200206)
                                                     H05B033-22
                                                                      <--
     KR 338251
                   В
                      20020527 (200277)
                                                     H05B033-22
ADT EP 1041654 A1 EP 2000-302731 20000331; JP 2000294376 A JP 1999-96212
     19990402; CN 1269690 A CN 2000-108665 20000331; KR 2001014660 A KR
     2000-16452 20000330; TW 443075 A TW 2000-106190 20000401; KR 338251 B KR
     2000-16452 20000330
FDT KR 338251 B Previous Publ. KR 2001014660
PRAI JP 1999-96212
                      19990402
     ICM H01L051-20; H05B033-00; H05B033-22
     ICS
         H05B033-14
AR
     EΡ
          1041654 A UPAB: 20001109
    NOVELTY - Light-emitting organic
     layer is located between hole-injecting
    electrode and negative electrode. High resistance
    inorganic hole-injecting layer located between the hole-injecting
    electrode and the organic layer contains silicon oxide
    and/or germanium oxide as a main component and a conductive oxide with
    resistivity up to 1 multiply 1010 Ohm -cm.
         DETAILED DESCRIPTION - The main component of the high
    resistance inorganic hole-injecting layer is represented by the
    formula: (Sil-xGex)Oy, where x = 0-1, and y = 1.7-2.2.
         The conductive oxide comprises at least one oxide selected from those
    of In, Zn, Ru and V.
         An inorganic insulative electron injecting and transporting layer can
    be located between the organic layer and the negative
    electrode, and it contains, as main component, at least one oxide selected
    from strontium oxide, magnesium oxide, calcium oxide, lithium oxide,
    rubidium oxide, potassium oxide, sodium oxide, and cesium oxide.
         USE - Organic electroluminescent device.
         ADVANTAGE - Improved hole injection efficiency, efficient
    hole-electron recombination in light-emitting layer,
    high light emission efficiency, low operating voltage,
    and low cost.
         DESCRIPTION OF DRAWING(S) - The drawing shows the configuration of an
    organic electroluminescent device according to an embodiment of
    the invention.
         Drive power supply E
         Hole-injecting electrode 2
         Electron-injecting electrode 3
           Light-emitting layer 5
```

```
Dwg.1/4
 FS
      CPI EPI
 FA,
      AB; GI
 MC
      CPI: L03-G05; L04-E03
      EPI: U14-J; X26-J
 L37
      ANSWER 19 OF 73 WPIX
                               (C) 2003 THOMSON DERWENT
 AN
      2000-453929 [40]
                         WPIX
DNN N2000-338153
                         DNC C2000-138442
     Low cost low operating voltage organic electro luminescent device with
 тT
      improved electron injection and luminous efficiency comprising an high
     resistance inorganic electron injecting layer capable of hole
     blocking.
DC
     L03 U14
     ARAI, M; KOBORI, I; MITSUHASHI, E; YAMAMOTO, H
IN
PA
      (DENK) TDK CORP
CYC 30
PΙ
     EP 1022788
                   A2 20000726 (200040)* EN
                                                13p
                                                       H01L051-20
         R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT
             RO SE SI
     JP 2000215983 A 20000804 (200042)
                                                      H05B033-22
     CN 1261249
                   Α
                      20000726 (200057)
                                                      H05B033-14
     KR 2000052291 A 20000816 (200121)
TW 421976 A 20010211 (200146)
                                                                       <--
                                                      H05B033-14
                                                                       <--
                                                      H05B033-22
                                                                       <--
     US 6281627
                   B1 20010828 (200151)
                                                      H01J001-62
     KR 323777
                   B 20020219 (200257)
                                                      H05B033-14
                                                                       <--
ADT EP 1022788 A2 EP 1999-305046 19990625; JP 2000215983 A JP 1999-13666
     19990121; CN 1261249 A CN 1999-111100 19990625; KR 2000052291 A KR
     1999-24287 19990625; TW 421976 A TW 1999-110781 19990625; US 6281627 B1 US
     1999-234704 19990121; KR 323777 B KR 1999-24287 19990625
FDT KR 323777 B Previous Publ. KR 2000052291
PRAI JP 1999-13666
                      19990121
     ICM H01J001-62; H01L051-20; H05B033-14;
          H05B033-22
          H01J063-04; H05B033-12
AB
          1022788 A UPAB: 20000823
     NOVELTY - The organic EL comprises a high resistance
     inorganic electron injecting layer between the hole injecting and the
     organic light emitting layer (4).
          DETAILED DESCRIPTION - The inorganic layer comprises an alkali metal,
     alkaline earth, or lanthanide oxide with a specified work function as a
     first component and a metallic element with a second specified work
    function as a second component. The inorganic layer has hole blocking
    characteristics and conduction paths for carrying electrons improving the
    efficiency of the device. Organic EL device comprises:
          (a) hole injecting electrode (2);
          (b) electron injecting electrode (3);
          (c) at least one organic layer between
    the electrodes with at least one layer having a light
    emitting function (5); and
         (d) high resistance inorganic electron injecting layer (6)
    between the electron injecting electrode and the light
```

emitting layer comprising a first component selected from oxide of alkali metal, alkaline earth, and lanthanide elements with a work function at most 4 eV, and a second component selected from metal with work function = 3 - 5 eV, the layer being capable of blocking holes and having a conduction path for carrying electrons. USE - Organic EL devices for displays.

```
ADVANTAGE - The device has excellent electron injection efficiency,
       improved luminous efficiency, low operating voltage, and low cost.
           DESCRIPTION OF DRAWING(S) - The drawing shows an organic electro
       luminescent device
       substrate 1
           hole injecting electrode 2
           electron injecting electrode 3
           hole injecting and transporting layer 4
             light emitting layer 5
           high resistance inorganic electron injecting layer 6
      Dwg.1/4
      CPI EPI
 FS
 FΑ
      AB; GI
 MC
      CPI: L03-C04
      EPI: U14-J02
 L37
      ANSWER 20 OF 73 WPIX
                              (C) 2003 THOMSON DERWENT
 ΑN
      2000-444459 [39]
                         WPTX
 DNN
     N2000-331616
                         DNC C2000-135409
 TI
     Organic electroluminescent device has inorganic insulative hole
     injecting and transporting layer between hole injecting electrode and
      light emitting layer.
DC
     L03 U14
     ARAI, M; KOBORI, I; MITSUHASHI, E
 ΙN
PA
     (DENK) TDK CORP
CYC 27
PΙ
     EP 1020939
                   A2 20000719 (200039)* EN
                                              11p
         R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT
                                                     H01L051-20
     JP 2000208277 A 20000728 (200041)
                                              10p
                                                     H05B033-22
     US 6208076
                   B1 20010327 (200119)
                                                                      <--
     EP 1020939 A2 EP 1999-305050 19990625; JP 2000208277 A JP 1999-6874
     19990113; US 6208076 B1 US 1999-229569 19990113
PRAI JP 1999-6874
                      19990113
     ICM H01L033-00; H01L051-20; H05B033-22
     ICS H05B033-00; H05B033-14
AΒ
          1020939 A UPAB: 20000818
    NOVELTY - The inorganic insulative hole injecting and transporting layer
     (4b) comprises silicon oxide and/or germanium oxide having an average
    composition of formula (Sil-xGex)Oy where 0 at most x at most 1 and 1 less
         DETAILED DESCRIPTION - The organic electroluminescent
    device comprises a hole injecting electrode, a negative electrode and at
    least two organic layers between the
    electrodes. The organic layers include a
    light emitting layer (5). The device further includes a
    hole injecting and transporting layer (4a) containing a hole transporting
    organic material and an inorganic insulative hole injecting and
    transporting layer (4b) between the hole injecting electrode and the
    light emitting layer. The inorganic insulative hole
    injecting and transporting layer comprises silicon oxide and/or germanium
    oxide having an average composition of formula (Si1-xGex)Oy where 0 at
   most x at most 1 and 1 less than y at most 2. Preferably the inorganic
   hole injecting and transporting layer has a thickness of up to 5 nm.
        USE - For organic electroluminescent device.
        ADVANTAGE - The device has an improved performance, a long life,
   weather resistance, high stability, high efficiency and low
```

```
DESCRIPTION OF DRAWING(S) - The drawing shows a cross-section of the
      device.
      Substrate 1
           Hole injecting electrode 2
           Electron injecting electrode 3
           Organic hole injecting and transporting layer 4a
           Inorganic insulative hole injecting and transporting layer 4b
             Light emitting layer 5
      Dwg.1/4
 FS
     CPI EPI
 FA
     AB; GI
MC
     CPI: L03-C02; L03-G05; L03-H04A
     EPI: U14-J02
L37 ANSWER 21 OF 73 WPIX
                              (C) 2003 THOMSON DERWENT
AN
     2000-444458 [39]
                        WPTX
DNN N2000-331615
                        DNC C2000-135408
ΤI
     Organic electroluminescent device having inorganic insulative
     electron injecting and transporting layer between negative electrode and
     light emitting layer.
DC
     L03 U14
     ARAI, M; KOBORI, I; MITSUHASHI, E
IN
PA
     (DENK) TDK CORP
CYC 27
PI
    EP 1020938
                   A2 20000719 (200039)* EN
                                              14p
                                                     H01L051-20
         R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT
            RO SE SI
     JP 2000208276 A 20000728 (200041)
                                              12p
                                                     H05B033-22
                                                                     <--
     US 6198219
                   B1 20010306 (200115)
                                                     H01L033-00
    EP 1020938 A2 EP 1999-305047 19990625; JP 2000208276 A JP 1999-6873
    19990113; US 6198219 B1 US 1999-229562 19990113
PRAI JP 1999-6873
                     19990113
    ICM H01L033-00; H01L051-20; H05B033-22
    ICS H05B033-00; H05B033-10; H05B033-14
         1020938 A UPAB: 20000818
    NOVELTY - The inorganic insulative electron injecting and transporting
    layer (5a) comprises at least one oxide selected from lithium, rubidium,
    potassium, sodium, cesium, strontium, magnesium and calcium oxide as a
    main component and silicon oxide and/or germanium oxide as a stabiliser.
         DETAILED DESCRIPTION - The device comprises a substrate (1), a hole
    injecting electrode and a negative electrode formed on the substrate, and
    an organic layer containing an organic
    material between the electrodes and including a
    light emitting layer (4). The device further comprises
    an electron injecting and transporting layer containing an electron
    transporting organic material and an inorganic insulative electron
    injecting and transporting layer (5a) formed on an inorganic material
    between the negative electrode (6) and the light
    emitting layer. The inorganic insulative electron injecting and
    transporting layer comprises at least one oxide selected from lithium,
    rubidium, potassium, sodium, cesium, strontium, magnesium and calcium
    oxide as a main component and silicon oxide and/or germanium oxide as a
    stabiliser.
        USE - For organic electroluminescent device.
        ADVANTAGE - The device has improved performance, a high efficiency,
   long life weather resistance and high stability.
        DESCRIPTION OF DRAWING(S) - The drawing shows a cross-sectional view
   of the device.
```

```
Substrate 1
          Hole injecting electrode 2
            Light emitting layer 4
          Inorganic insulative electron injecting layer 5a
          Organic electron injecting and transporting layer 5b
          Negative electrode or electron injecting electrode 6
     Dwg.1/4
     CPĪ EPI
FS
    AB; GI
FA
     CPI: L03-C02; L03-G05; L03-H04A
MC
     EPI: U14-J02
                             (C) 2003 THOMSON DERWENT
L37 ANSWER 22 OF 73 WPIX
     2000-389345 [34]
                        WPIX
AN
DNN N2000-291549
                        DNC C2000-118416
     Organic electroluminescent device includes an organic
TΤ
     light emitting layer located between an
     inorganic electron injecting and transporting layer and an inorganic
     insulative hole injecting and transporting layer.
     L03 U14 X26
DC
     ARAI, M; KOBORI, I; MITSUHASHI, E
IN
     (DENK) TDK CORP
PA
CYC 27
                  A2 20000614 (200034)* EN
                                             13p
                                                     H01L051-20
PΙ
         R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT
            RO SE SI
                                                                     <--
     JP 2000173776 A 20000623 (200036)
                                              11p
                                                     H05B033-22
     US 6296954
                 B1 20011002 (200160)
                                                     H05B033-00
                                                                     <--
     EP 1009045 A2 EP 1999-305044 19990625; JP 2000173776 A JP 1998-363790
ADT
     19981207; US 6296954 B1 US 1999-235379 19990122
PRAI JP 1998-363790
                      19981207
     ICM H01L051-20; H05B033-00; H05B033-22
IC
     ICS
          H05B033-14
          1009045 A UPAB: 20000718
AB
     NOVELTY - An organic luminescent device includes an organic
     light emitting layer (5) between an inorganic
     electron injecting and transporting layer (6) and an inorganic insulative
     hole injecting and transporting layer (4).
          DETAILED DESCRIPTION - An organic luminescent device comprises:
          (a) a substrate (1);
          (b) a hole injecting electrode (2) and negative electrode (3) formed
     on the substrate;
          (c) a light emitting layer (5)
     containing an organic material between the
          (d) an inorganic electron injecting and transporting layer (6)
     between the light emitting layer and the negative
     electrode;
          (e) an inorganic insulative hole injecting and transporting layer (4)
     between the light emitting layer and the hole
     injecting electrode.
          The inorganic electron injecting and transporting layer comprises at
     least one oxide selected from strontium oxide, magnesium oxide, calcium
     oxide, lithium oxide, rubidium oxide, potassium oxide, sodium oxide, and
     cesium oxide as a main component.
```

The inorganic insulative hole injecting and transporting layer comprises silicon oxide or germanium oxide or a mixture of these as a main

```
component. The main component is of formula (I):
          where 0 at most x at most 1; and 1.7 at most y at most 1.99, as
     analyzed by Rutherford back-scattering.
          USE - None given.
          ADVANTAGE - The device has a long life, weather resistance,
     high stability, high efficiency and is low in cost. The device is easy to
     manufacture and has stable physical properties at the film interface even
     when the light emitting layer consists of two or more
          DESCRIPTION OF DRAWING(S) - The diagram is a schematic
     cross-sectional view of the organic electroluminescent device.
     Substrate 1
          Hole injecting electrode 2
          Negative electrode 3
          Inorganic insulative hole injecting and transporting layer 4
            Light emitting layer 5
          Inorganic electron injecting layer 6
     Dwg.1/3
     CPI EPI
FS
FA
     AB; GI
     CPI: L04-E03
MC
     EPI: U14-J; X26-J
     ANSWER 23 OF 73 WPIX
L37
                             (C) 2003 THOMSON DERWENT
AN
     2000-273653 [24]
                        WPIX
DNN N2000-205155
                        DNC C2000-083626
TΙ
     Organic electroluminescent device includes an inorganic
     insulating electron injecting and transporting layer comprising three
     oxide components.
DC
     L03 U12 U14 X26
IN
    ARAI, M; KOBORI, I; MITSUHASHI, E
PA
    (DENK) TDK CORP
CYC 27
PΤ
    EP 994517
                  A2 20000419 (200024)* EN
                                              12p
                                                     H01L051-20
         R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT
            RO SE SI
     JP 2000123976 A 20000428 (200032)
                                              10p
                                                     H05B033-22
                                                                     <--
    US 6303239
                 B1 20011016 (200164)
                                                     H01L033-00
                                                                     <--
   EP 994517 A2 EP 1999-305041 19990625; JP 2000123976 A JP 1998-303350
    19981009; US 6303239 B1 US 1999-241284 19990201
PRAI JP 1998-303350
                     19981009
TC
    ICM H01L033-00; H01L051-20; H05B033-22
         H05B033-00; H05B033-14; H05B033-26
    ICS
AB
          994517 A UPAB: 20000522
    NOVELTY - Organic electroluminescent device includes an
    inorganic insulating electron injecting and transporting layer (6) which
    comprises: a first component comprising lithium oxide, rubidium oxide,
    potassium oxide, sodium oxide and/or caesium oxide; a second component
    comprising strontium oxide, magnesium oxide and/or calcium oxide; and a
    third component comprising silicon oxide and/or germanium oxide.
         DETAILED DESCRIPTION - Organic electroluminescent (
    EL) device comprises a substrate (1), a hole injecting electrode
    (2) and a cathode (3) formed on the substrate, and an organic
    layer (5) between the electrodes and
    participating in at least a light emission function.
    An inorganic insulating electron injecting and transporting layer (6) is
    located between the organic layer and the cathode. The
    inorganic insulating electron injecting and transporting layer comprises:
```

```
(i) a first component comprising at least one of lithium oxide,
      rubidium oxide, potassium oxide, sodium oxide and caesium oxide;
            (ii) a second component comprising at least one of strontium oxide,
      magnesium oxide and calcium oxide; and
           (iii) a third component comprising silicon oxide and/or germanium
      oxide.
           USE - None given.
           ADVANTAGE - Organic EL device has an extended life, weather
      resistance, high stability, and high efficiency and is
      inexpensive.
           DESCRIPTION OF DRAWING(S) - The diagram shows a sectional schematic
      of one embodiment of the organic electroluminescent device.
      Substrate 1
           Hole injecting electrode 2
      Cathode 3
           Hole injecting and transporting layer 4
             Light emitting layer 5
           Inorganic insulating electron injecting and transporting layer 6
      Dwg.1/4
FS
     CPI EPI
FΑ
     AB; GI
MC
     CPI: L03-H04A
     EPI: U12-A01A1X; U14-J02; X26-J
     ANSWER 24 OF 73 INSPEC COPYRIGHT 2003 IEE
L37
                                                        DUPLICATE 3
AN
     2001:6815663 INSPEC
                              DN B2001-02-4260D-018
     Surface roughness effects and their influence on the degradation of
TI
     organic light emitting devices.
     Jonda, Ch.; Mayer, A.B.R.; Stolz, U. (Corp. Res. & Dev., Robert Bosch
     GmbH, Gerlingen, Germany); Elschner, A.; Karbach, A.
     Journal of Materials Science (15 Nov. 2000) vol.35, no.22, p.5645-51. 15
SO
     Published by: Kluwer Academic Publishers
     Price: CCCC 0022-2461/2000/$15.00
     CODEN: JMTSAS ISSN: 0022-2461
     SICI: 0022-2461(20001115)35:22L.5645:SRET;1-0
DT
     Journal
TC
     Experimental
CY
     United States
LΑ
     English
AΒ
     Organic light emitting devices typically consist of
     one or several organic layers which are sandwiched
     between two electrodes, one of which has to be
     transparent. In most cases indium tin oxide (ITO) is employed as the
     transparent, hole-injecting anode material. Usually, the functional
     organic layers possess a thickness of about 100 nm. For such thin films
    the homogeneity and the surface roughness are especially important factors
     for the device performance. Therefore, the surface roughness of all those
    layers which are the basis for subsequent deposition processes were
    systematically studied by atomic force microscopy (AFM). For these
    investigations both the ITO substrate and the layers consisting of
    different organic materials deposited onto the ITO substrate were
    analyzed. In addition, the two different basic deposition methods for the
    organic materials, namely the deposition from solution by spin coating and
    the deposition by thermal evaporation, were compared to one another with
    respect to their resulting surface roughness. It was found that the large
    surface roughness of the ITO substrate induces layer inhomogeneities,
    especially for the vapor deposited organic layers. They can be reduced by
```

- the incorporation of a polymeric smoothing layer.
- B4260D Light emitting diodes; B0520X Other thin film deposition CC techniques; B0540 Ceramics and refractories (engineering materials science)
- ATOMIC FORCE MICROSCOPY; CERAMICS; INDIUM COMPOUNDS; LIGHT EMITTING DEVICES; ORGANIC COMPOUNDS; ROUGH SURFACES; SPIN COATING; SURFACE TOPOGRAPHY
- ST organic light emitting devices degradation; surface roughness effects; polymeric smoothing layer; transparent hole-injecting anode material; atomic force microscopy; AFM; ITO substrate; 100 nm; ITO; InSnO
- CHI InSnO sur, In sur, Sn sur, O sur, InSnO ss, In ss, Sn ss, O ss
- PHP size 1.0E-07 m
- In*O*Sn; In sy 3; sy 3; O sy 3; Sn sy 3; InSnO; In cp; cp; Sn cp; O cp; ET In; Sn; O
- ANSWER 25 OF 73 INSPEC COPYRIGHT 2003 IEE L37
- 2000:6633294 INSPEC AN DN B2000-08-4260D-009
- Improving the performance of doped pi -conjugated polymers for use in ΤI organic light-emitting diodes.
- ΑU Gross, M.; Muller, D.C. (Inst. fur Phys., Ludwig-Maximilians-Univ., Munchen, Germany); Nothofer, H.-G.; Scherf, U.; Neher, D.; Brauchle, C.; Meerholz, K.
- SO Nature (8 June 2000) vol.405, no.6787, p.661-5. 21 refs. Published by: Macmillan Magazines Price: CCCC 0028-0836/2000/\$12.00+2.00 CODEN: NATUAS ISSN: 0028-0836 SICI: 0028-0836(20000608)405:6787L.661:IPDC;1-0
- DT Journal
- TC Application; Experimental
- CY United Kingdom
- LΑ English
- AΒ Organic light-emitting diodes (OLEDs) represent a promising technology for large, flexible, lightweight, flat-panel displays. Such devices consist of one or several semiconducting organic layer(s) sandwiched between two electrodes. When an electric field is applied, electrons are injected by the cathode into the lowest unoccupied molecular orbital of the adjacent molecules (simultaneously, holes are injected by the anode into the highest occupied molecular orbital). The two types of carriers migrate towards each other and a fraction of them recombine to form excitons, some of which decay radiatively to the ground state by spontaneous emission. Doped pi -conjugated polymer layers improve the injection of holes in OLED devices; this is thought to result from the more favourable work function of these injection layers compared with the more commonly used layer material (indium tin oxide). Here we demonstrate that by increasing the doping level of such polymers, the barrier to hole injection can be continuously reduced. The use of combinatorial devices allows us to quickly screen for the optimum doping level. We apply this concept in **OLED** devices with hole-limited electroluminescence (such as polyfluorene-based systems), finding that it is possible to significantly reduce the operating voltage while improving the light output and efficiency.
- B4260D Light emitting diodes; B7260B Display materials; B2550B CC Semiconductor doping; B0560 Polymers and plastics (engineering materials science)
- CONDUCTING POLYMERS; EXCITONS; LED DISPLAYS; ORGANIC SEMICONDUCTORS; CT SEMICONDUCTOR DOPING
- performance; doped pi -conjugated polymers; organic light-emitting ST

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LΑ

IC

PΙ

ST

IT

diodes; OLEDs; flat-panel displays; semiconducting organic layer; excitons; ground state; spontaneous emission; injection of holes; work function; injection layers; doping level; barrier to hole injection; combinatorial devices; optimum doping level; hole-limited electroluminescence; polyfluorene-based systems; operating voltage; light output; efficiency ANSWER 26 OF 73 HCAPLUS COPYRIGHT 2003 ACS 1999:753452 HCAPLUS 132:7422 An improved electrode structure for organic light emitting diode devices Jones, Gary W.; Howard, Webster E. Fed Corporation, USA PCT Int. Appl., 14 pp. CODEN: PIXXD2 Patent English ICM H01J001-62 ICS H01J001-63; H01L035-24; H01L033-00 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties) Section cross-reference(s): 76 FAN.CNT 1 PATENT NO. KIND DATE APPLICATION NO. DATE ____ -----WO 9960599 19991125 **A**1 WO 1999-US3900 19990224 W: CN, JP, KR, US RW: AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE EP 1088320 20010404 **A**1 EP 1999-909560 R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT, 19990224 IE, FI JP 2002516459 T2 20020604 JP 2000-550128 19990224 US 2002021088 A1 20020221 US 2001-919467 20010731 PRAI US 1998-85910P Ρ 19980518 US 1998-85911P Р 19980518 WO 1999-US3900 W 19990224 Org. light-emitting diode devices having a first electrode, a second electrode, and an org. stack interposed between the first electrode and the second electrode, the org. stack including hole transport materials located on one side and electron transport materials located on another side are described in which a thin layer of high work function material is interposed between the first electrode and the org. stack. The high work function material may be selected from the group consisting of Mo and its alloys, W and its alloys, and Nb, Zr, Co, Zn, Tc, Hf, Ta, Cr, Au, Pt, Pd, Se, and Ni or alloys contg. .gtoreq.1 of them. Org. light-emitting diode devices comprising an anode layer formed from a high work function material; an org. stack having hole transport materials located on one side of the stack and electron transport materials located on another side of the org. stack; a transport electrode layer; and a thin layer of a low work function material located between the org. stack and the transport layer are also described. org light emitting diode electrode

Electric contacts Electrodes

```
Electroluminescent devices
           (electrode structures for org. light-emitting diode
           devices)
   IT
        Chromium alloy, nonbase
        Cobalt alloy, nonbase
        Gold alloy, nonbase
        Hafnium alloy, nonbase
        Molybdenum alloy, nonbase
        Nickel alloy, nonbase
       Niobium alloy, nonbase
        Palladium alloy, nonbase
       Platinum alloy, nonbase
       Selenium alloy, nonbase
       Tantalum alloy, nonbase
       Technetium alloy, nonbase
       Tungsten alloy, nonbase
       Zinc alloy, nonbase
       Zirconium alloy, nonbase
       RL: DEV (Device component use); USES (Uses)
          (electrode structures for org. light-emitting diode
          devices)
       7439-98-7, Molybdenum, uses
                                     7440-02-0, Nickel, uses
       Niobium, uses 7440-05-3, Palladium, uses 7440-06-4, Platinum, uses
      7440-25-7, Tantalum, uses 7440-26-8, Technetium, uses 7440-33-7, Tungsten, uses 7440-47-3, Chromium, uses 7440-48-4, Cobalt, uses
       7440-57-5, Gold, uses 7440-58-6, Hafnium, uses 7440-66-6, Zinc, uses
       7440-67-7, Zirconium, uses 7782-49-2, Selenium, uses
      RL: DEV (Device component use); USES (Uses)
          (electrode structures for org. light-emitting diode
          devices)
 RE.CNT
               THERE ARE 2 CITED REFERENCES AVAILABLE FOR THIS RECORD
 (1) Haight; US 5714838 A 1998 HCAPLUS
 (2) Hirai; US 5820996 A 1998 HCAPLUS
 L37 ANSWER 27 OF 73 HCAPLUS COPYRIGHT 2003 ACS
 AN
      1999:582707 HCAPLUS
 DN
      131:191702
      Encapsulated organic light emitting device
 TI
     Haskal, Eliav; Karg, Siegfried; Salem, Jesse Richard; Scott, John Campbell
 IN
     International Business Machines Corporation, USA
 PA
 SO
     U.S., 6 pp.
     CODEN: USXXAM
DT
     Patent
LΑ
     English
IC
     ICM H01J001-62
     ICS H01J063-04
NCL
     313504000
     73-11 (Optical, Electron, and Mass Spectroscopy and Other Related
     Section cross-reference(s): 76
FAN.CNT 1
     PATENT NO.
                      KIND DATE
                                            APPLICATION NO.
                                                             DATE
                            -----
PI
     US 5952778
                       Α
                            19990914
                                            US 1997-820219
     TW 424406
                                                             19970318
                       В
                            20010301
                                            TW 1998-87103764 19980313
PRAI US 1997-820219 A
                            19970318
     Light-emitting devices comprising an
```

ΙT

IT

IT

IT

RF.

org. active layer sandwiched between first and second electrodes, the first electrode contiguous to a transparent substrate and the second electrode contiguous to a protective covering are described in which the second electrode comprises an alkali metal, alk. earth metal, or rare earth metal and the protective covering comprises a first layer of gold, silver, indium, aluminum, or a transition metal directly on and in contact with the second electrode, a second layer of dielec. material 50-500 nm thick directly on and in contact with the first layer and selected from silicon nitride, silicon oxide, germanium oxide, and zirconium oxide, and a third layer of hydrophobic polymer directly on and in contact with the second layer. The second electrode may comprise calcium, lithium, or magnesium. The polymer may be a polysiloxane, polytetrafluoroethylene, or polyolefin. The protective covering may further comprises an impact-resistant fourth layer of glass or metal. encapsulated org light emitting device ST Electroluminescent devices Electronic packaging materials (multilayer systems for encapsulating org. lightemitting devices) Alkali metals, uses Alkaline earth metals Fluoropolymers, uses Glass, uses Polyolefins Polysiloxanes, uses Rare earth metals, uses Transition metals, uses RL: DEV (Device component use); USES (Uses) (multilayer systems for encapsulating org. lightemitting devices) 7439-95-4, Magnesium, uses RL: DEV (Device component use); USES (Uses) (electrode; multilayer systems for encapsulating org. light-emitting devices) 147-14-8, Copper phthalocyanine 1310-53-8, Germanium oxide, uses 1314-23-4, Zirconium oxide, uses 2085-33-8, Tris(8hydroxyquinolinato)aluminum 7429-90-5, Aluminum, uses **7439-93-2** , Lithium, uses 7440-22-4, Silver, uses 7440-57-5, Gold, uses **7440-70-2**, Calcium, uses 7440-74-6, Indium, uses 7631-86-9, Silicon oxide, uses 9002-84-0, Polytetrafluoroethylene 12033-89-5, Silicon nitride, uses 113443-18-8, Silicon monoxide 117665-21-1 138184-36-8, MEH-PPV RL: DEV (Device component use); USES (Uses) (multilayer systems for encapsulating org. lightemitting devices) RE.CNT THERE ARE 22 CITED REFERENCES AVAILABLE FOR THIS RECORD (1) Benjamin; US 4983310 1991 HCAPLUS (2) Farng; US 5169547 1992 HCAPLUS (3) Friend; US 5247190 1993

- (4) Harvey; US 5757126 1998 HCAPLUS
- (5) Harvey; US 5771562 1998 HCAPLUS
- (6) Hashimoto; US 5214306 1993 HCAPLUS
- (7) Hegger; US 5408109 1995 HCAPLUS
- (8) Holm; US 5449926 1995
- (9) Karol; US 5391756 1995 HCAPLUS

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(10) Kido, J; Cecri 1994, P1 HCAPLUS
 (11) Konishikawa; US 5337374 1994
 (12) Leventis; US 5189549 1993 HCAPLUS
 (13) Ogata; US 5296724 1994
 (14) Okorodudu; US 5362410 1994 HCAPLUS
 (15) Ozawa; US 5373175 1994 HCAPLUS
 (16) Pei, Q; Science 1995, V269, P1086 HCAPLUS
 (17) Reamey; US 5328580 1994 HCAPLUS
 (18) Shi; US 5593788 1997 HCAPLUS
 (19) Shi; US 5811177 1998
 (20) Tang; US 4356429 1982 HCAPLUS
 (21) VanSlyke; US 4539507 1985
 (22) Yamashita; US 5124204 1992
 L37 ANSWER 28 OF 73 HCAPLUS COPYRIGHT 2003 ACS
    1999:756257 HCAPLUS
 AN
 DN
     132:17194
 TΙ
     Organic EL displays and their manufacture
     Kodama, Mitsufumi; Nakatani, Kenji
     TDK Electronics Co., Ltd., Japan
     Jpn. Kokai Tokkyo Koho, 16 pp.
 SO
     CODEN: JKXXAF
DT
     Patent
LΑ
     Japanese
IC
     ICM H05B033-26
     ICS H05B033-10; H05B033-12; H05B033-14; H05B033-22
     74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other
     Reprographic Processes)
     Section cross-reference(s): 73
FAN.CNT 1
     PATENT NO.
                  KIND DATE
                                          APPLICATION NO. DATE
                     ----
                                           -----
                                                           ______
     JP 11329749
                     A2 19991130
                                           JP 1998-146624
                                                           19980512
PRAI JP 1998-146624
                      19980512
     The device comprises a substrate having a 1st electrode,
     .gtoreq.2 org. layers having light-emitting
     effect, and a 2nd electrode in the order, with elec. floating internal
     electrode formed in between the org.
     layers. EL displays are manufd. by formation of a 1st
     electrode on a substrate, formation of an insulator, formation of an
     electrode structure having a over-hanged part and an elec. conducting base
     part, formation of .gtoreq.2 org. light-
     emitting layers with in-between floating
     electrode, and formation of a 2nd electrode. Color displays
     showing high brightness are obtained with less wirings.
ST
     org EL display floating electrode
IT
     Electroluminescent devices
        (manuf. of org. EL displays with floating electrodes
        in between org. EL layers)
ΙT
     Glass, uses
     RL: DEV (Device component use); USES (Uses)
        (spin-on-glass, insulation layer in; manuf. of org.
       EL displays with floating electrodes in
       between org. EL layers)
IT
    2085-33-8, Tris(8-hydroxyquinoline)aluminum
                                                  158605-06-2
    RL: DEV (Device component use); USES (Uses)
        (EL layer; manuf. of org. EL displays
       with floating electrodes in between org.
```

```
EL layers)
      7429-90-\bar{5}, Aluminum, uses 7440-47-3, Chromium, uses 12614-86-7
 IT
      143010-15-5, Magnesium 91, silver 9
      RL: DEV (Device component use); USES (Uses)
         (electrode; manuf. of org. EL displays with floating
         electrodes in between org. EL
         layers)
 IT
      50926-11-9, ITO
      RL: DEV (Device component use); USES (Uses)
         (floating electrode; manuf. of org. EL displays with floating
         electrodes in between org. EL
         lavers)
 IT
      7631-86-9, Silica, uses
      RL: DEV (Device component use); USES (Uses)
         (insulation layer in; manuf. of org. EL displays
         with floating electrodes in between org.
        EL layers)
 L37 ANSWER 29 OF 73 HCAPLUS COPYRIGHT 2003 ACS
     1999:708080 HCAPLUS
 DN
     131:315650
ΤI
     Organic EL (electroluminescent) device
     showing improved heat and weather resistance
IN
     Arai, Sachio
     TDK Electronics Co., Ltd., Japan
PA
     Jpn. Kokai Tokkyo Koho, 9 pp.
SO
     CODEN: JKXXAF
DT
     Patent
LΑ
     Japanese
IC
     ICM H05B033-22
     ICS C09K011-00; C09K011-06; H05B033-14; H05B033-26
CC
     73-11 (Optical, Electron, and Mass Spectroscopy and Other Related
     Properties)
FAN.CNT 1
     PATENT NO.
                      KIND DATE
                                           APPLICATION NO.
                                                           DATE
     _____
                      ----
                                           -----
     JP 11307267
PТ
                      A2 19991105
                                           JP 1998-122975
                                                            19980416
PRAI JP 1998-122975
                           19980416
     In the EL device comprising a substrate, a pair of
     electrodes, and .gtoreq.1 light-emitting org
     . layer between the electrodes; elec.
     insulating layers are arranged between the org. layer
     and both the electrode. The insulating layers works as elec.
     capacitors and generate dielec. polarization upon application of a voltage
     to the device, leading to recombination of electrons and holes,
     so that the EL device inhibits leak current and dark
     spot generation and shows improved heat and weather resistance without a
     hole-injection layer and an electron-injection layer.
ST
     org EL device insulator layer;
     electroluminescent org device dielec capacitor
     layer
ΙT
     Electric insulators
      Electroluminescent devices
        (org. EL device having dielec.
        layers between org. layer and
        electrodes showing improved heat and weather resistance)
     1304-28-5, Barium oxide, uses
IT
                                   1305-78-8, Calcia, uses 1313-96-8,
                    1314-11-0, Strontium oxide, uses 1314-23-4, Zirconia,
    Niobium oxide
```

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uses 1314-61-0, Tantalum oxide 1335-25-7, Lead oxide 1344-28-1, Alumina, uses 7631-86-9, Silica, uses 12033-89-5,
     Silicon nitride (si3n4), uses 12055-23-1, Hafnium oxide
     12057-24-8, Lithium oxide, uses 13463-67-7, Titania,
     RL: DEV (Device component use); USES (Uses)
         (elec. insulator; org. EL device having
        dielec. layers between org. layer
        and electrodes showing improved heat and weather resistance)
L37 ANSWER 30 OF 73 HCAPLUS COPYRIGHT 2003 ACS
     1999:426975 HCAPLUS
DN
     131:80832
     Light-transmitting, reflection-type, and electroluminescent
TΙ
     display device
     Yamazae, Hiroshi; Wakita, Naohide; Yamanaka, Yasuhiko; Ezawa, Takeshi;
     Kawaguri, Mariko
     Matsushita Electric Industrial Co., Ltd., Japan
PA
     Jpn. Kokai Tokkyo Koho, 8 pp.
SO
     CODEN: JKXXAF
DT
     Patent
LΑ
     Japanese
IC
     ICM G02F001-136
     ICS G02F001-1345
     74-12 (Radiation Chemistry, Photochemistry, and Photographic and Other
     Reprographic Processes)
FAN.CNT 1
     PATENT NO.
                    KIND DATE
                                           APPLICATION NO. DATE
     -----
                     ----
                                           ______
     JP 11183935
PΙ
                     A2 19990709
                                           JP 1997-352613 19971222
PRAI JP 1997-352613
                      19971222
     The device has a (reflection-type) pixel electrode and a
     Si-integrated chip formed on a multilayer wiring on an
     insulating substrate and a liq. crystal layer between the
     electrode and counter substrates, in which the chip is elec. contacted to
     the electrode via the wiring. The device has a pixel electrode
     and a Si-integrated chip formed on a multilayer wiring on an
     insulating substrate and an org. elec.-field light-
     emitting layer between counter
     electrodes, in which the chip is elec. contacted to the electrode
     via the wiring. The device gives good images with high
     contrast.
     light transmitting liq crystal display device; reflection type
ST
     liq crystal display device; electroluminescent type
     liq crystal display
IΤ
     Liquid crystal displays
        (liq. crystal display device with high contrast)
ΙT
     7440-21-3, Silicon, uses
     RL: DEV (Device component use); USES (Uses)
        (liq. crystal display device with high contrast)
L37
    ANSWER 31 OF 73 WPIX
                             (C) 2003 THOMSON DERWENT
AN
     1999-280493 [24] WPIX
DNN N1999-210367
                       DNC C1999-082613
ΤI
     Sputter deposition method for the manufacture of organic light
     emitting device.
DC.
    A26 A35 A85 L03 M13 U11 U12
IN
    CARTER, J; HEEKS, S K
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(CAMB-N) CAMBRIDGE DISPLAY TECHNOLOGY LTD
 CYC
     82
 PΙ
      GB 2331765
                    A 19990602 (199924)*
                                               16p
                                                      C23C014-20
      WO 9928521
                    A1 19990610 (199930) EN
                                                      C23C014-20
         RW: AT BE CH CY DE DK EA ES FI FR GB GH GM GR IE IT KE LS LU MC MW NL
             OA PT SD SE SZ UG ZW
          W: AL AM AT AU AZ BA BB BG BR BY CA CH CN CU CZ DE DK EE ES FI GB GE
             GH GM HR HU ID IL IS JP KE KG KP KR KZ LC LK LR LS LT LU LV MD MG
             MK MN MW MX NO NZ PL PT RO RU SD SE SG SI SK SL TJ TM TR TT UA UG
             US UZ VN YU ZW
      AU 9911687
                    A 19990616 (199945)
                                                      C23C014-20
     GB 2331765 A GB 1997-25434 19971201; WO 9928521 A1 WO 1998-GB3489
 ADT
      19981120; AU 9911687 A AU 1999-11687 19981120
 FDT AU 9911687 A Based on WO 9928521
 PRAI GB 1997-25434
                       19971201
      ICM C23C014-20
      ICS H01L033-00; H01L051-20; H05B033-14
 ΑB
           2331765 A UPAB: 19990624
     NOVELTY - Sputter deposition on to an organic material comprises using a
      discharge gas with a spectrum of light emission of a
      lower energy than that of argon.
           DETAILED DESCRIPTION - INDEPENDENT CLAIMS are also included for: (1)
      the manufacture of an organic light emitting device
      comprising forming a first electrode, providing an organic
      light emissive layer adjacent the first
     electrode, and sputter depositing a second electrode on the previous layer
     by a sputtering process in which neon is used as the discharge gas; and
      (2) for an organic light emitting device.
          USE - Sputter deposition method for the manufacture of organic
     light emitting device.
          ADVANTAGE - After the sputter deposition is complete, less damage to
     the organic layer is obtained compared to a process
     using argon. The rectification ratio of an organic light
     emitting device having a cathode which is sputter deposited using
     neon as the discharge gas is typically 100 times better than that of a
     device having a cathode sputter deposited using argon. Sputtering directly
     on to sensitive soluble organic layers such as MEH-PPV
     is feasible with neon as the discharge gas.
FS
     CPI EPI
FA
     CPI: A05-J; A11-C04B; A12-E11; L03-C04; L03-D01D; L03-G05; M13-G01
MC
     EPI: U11-C01A3; U11-C01J5; U12-A01A1X; U12-A01A2
     ANSWER 32 OF 73 WPIX
L37
                             (C) 2003 THOMSON DERWENT
     2000-064722 [06]
AN
                        WPIX
     2000-064721 [06]
CR
DNN N2000-050778
                        DNC C2000-018225
TI
     Inorganic-organic junction structure in an organic
     electroluminescent device.
DC
     L03 U14 X26
IN
     ARAI, M; KOBORI, I; MITSUHASHI, E
PA
     (DENK) TDK CORP
CYC 26
PΙ
     EP 967669
                   A2 19991229 (200006)* EN
                                              12p
                                                     H01L051-20
         R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT
            RO SE SI
     US 6200695
                  B1 20010313 (200120)
                                                     H05B033-13
    EP 967669 A2 EP 1999-305045 19990625; US 6200695 B1 US 1998-207660
ADT
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THOMPSON 09/868351 Page 40
      19981209
 PRAI JP 1998-347946
                      19981120; JP 1998-196727 19980626
 IC
      ICM H01L051-20; H05B033-13
 AΒ
            967669 A UPAB: 20010410
      NOVELTY - An organic electroluminescent device comprises an
      inorganic insulating hole injecting layer (4) between the hole injecting
      electrode (2) and at least one organic layer, it
      consists of silicon oxide or germanium oxide or a mixture of silicon oxide
      and germanium oxide and has an average composition represented by the
      formula:
           (Si1-xGex)Oy where x is 0-1, y is 1.7-1.99 as analyzed by Rutherford
      back-scattering.
           DETAILED DESCRIPTION - An organic electroluminescent device
      comprises a hole injecting electrode (2), an electron injecting electrode
      (3), at least one organic layer between the
      electrodes, and an inorganic insulating hole injecting layer (4)
     between the hole injecting electrode and the at least one organic
     layer. The inorganic insulating hole injecting layer consists of
     silicon oxide or germanium oxide or a mixture of silicon oxide and
     germanium oxide and has an average composition represented by the formula:
           (Si1-xGex)Oy where x is 0-1, y is 1.7-1.99 as analyzed by Rutherford
     back-scattering.
          USE - Organic electroluminescent device, particularly an
     inorganic/organic junction structure.
          ADVANTAGE - The organic electroluminescent device has heat
     resistance, an extended effective life, an improved efficiency, a
     low drive voltage and a low cost.
          DESCRIPTION OF DRAWING(S) - The drawing shows the configuration of an
     organic electroluminescent device of the invention.
     Substrate 1
          Hole injecting electrode 2
          Electron injecting electrode 3
          Inorganic insulating hole injecting layer 4
            Light emitting layer 5
     Dwg.1/4
FS
     CPI EPI
FA
     AB; GI
MC
     CPI: L03-C04
     EPI: U14-J; X26-J
     ANSWER 33 OF 73 WPIX
L37
                             (C) 2003 THOMSON DERWENT
AN
     1999-280163 [24]
                        WPIX
DNN N1999-210155
                        DNC C1999-082509
ΤI
     Organic electroluminescent device.
DC
     L03 U11 U14 X26
IN
     KIM, S T; KIM, S
     (GLDS) LG ELECTRONICS INC; (GLDS) KINSEISHA KK
PA
CYC 29
     EP 917410
РΤ
                  A1 19990519 (199927) * EN
                                              10p
                                                     H05B033-10
         R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT
            RO SE SI
     JP 11111465 A 19990423 (199927)
                                               5p
                                                     H05B033-22
                                                                     <--
     CN 1211829
                  A 19990324 (199931)
                                                     H01L051-00
                                                                     <--
     KR 99025797 A 19990406 (200025)
                                                     H01L033-00
                                                                     <--
     US 6099746
                  A 20000808 (200040)
                                                     B05D005-12
     KR 244185
                  B1 20000201 (200118)
                                                     H01L033-00
ADT
   EP 917410 A1 EP 1998-303389 19980430; JP 11111465 A JP 1998-197821
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19980713; CN 1211829 A CN 1998-108714 19980529; KR 99025797 A KR

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THOMPSON 09/868351 Page 41
      1997-47579 19970918; US 6099746 A US 1998-58293 19980410; KR 244185 B1 KR
      1997-47579 19970918
 PRAI KR 1997-47579
                       19970918
      ICM B05D005-12; H01L033-00; H01L051-00;
           H05B033-10; H05B033-22
           B05D005-06; H05B033-02; H05B033-14
 AB
            917410 A UPAB: 19990719
      NOVELTY - Organic electroluminescent device includes insulating
      partition walls (13) of trapezoidal shape for isolating adjacent pixels.
           DETAILED DESCRIPTION - An electroluminescent device has
      pixels formed of first (12) and second electrode (15) stripes
      sandwiching an organic EL layer. An
     insulating partition wall projects from the first electrode stripe, the
     wall having a trapezoidal structure with a lower side wider than the upper
      side. Portions of the second electrode, and possibly the EL
     multilayer (14), formed on the top of the wall are etched out and
     any two adjacent pixels are electrically isolated. The partition wall is
     preferably formed of photoresist, silicon nitride or silicon oxide.
          USE - Especially as a flat panel display device.
          ADVANTAGE - Adequate pixellation is achieved using simple, stable
     partition walls which are easily fabricated.
          DESCRIPTION OF DRAWING(S) - The drawing shows the organic EL
     device of the invention
          Transparent substrate 11
          First electrode stripes 12
          Partition walls 13
            Organic EL layer 14
          Second electrode stripes 15
     Dwq.2e/2
FS
     CPI EPI
FA . AB; GI
MC
     CPI: L03-C04
     EPI: U11-C08; U14-J; X26-J
L37 ANSWER 34 OF 73 WPIX
                             (C) 2003 THOMSON DERWENT
AΝ
     1999-314914 [27]
                        WPIX
DNN N1999-235369
                        DNC C1999-093158
     Long lifetime organic electroluminescent devices.
ΤI
     Ell El2 L03 Ul2 Ul4 X26
DC
     KIM, M S; KIM, S T; OH, H Y; YOON, J G
TN
     (GLDS) LG ELECTRONICS CO LTD; (GLDS) LG ELECTRONICS INC; (GLDS) KINSEISHA
PA
     KK
CYC 29
PΙ
                   A2 19990519 (199927)* EN 116p
                                                     H01L051-20
         R: AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT
            RO SE SI
     CN 1217582
                  A 19990526 (199939)
                                                     H01L033-00
                                                                     <--
     JP 11233263
                  A 19990827 (199945)
                                              17p
                                                     H05B033-22
                                                                     <--
     KR 99044817
                  Α
                     19990625 (200036)
                                                     H01L033-00
                                                                     <--
     US 6248458
                   B1 20010619 (200137)
                                                     H05B033-12
                                                                     <--
     KR 2001021486 A 20010315 (200159)#
                                                     C09K011-00
     US 2001031380 A1 20011018 (200166)
                                                     H05B033-12
                                                                     <==
     KR 313912
                  B 20011116 (200240)#
                                                     C09K011-00
     KR 320455
                  B 20020219 (200257)
                                                     C09K011-00
    EP 917216 A2 EP 1998-306710 19980821; CN 1217582 A CN 1998-116616
ADT
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19980728; JP 11233263 A JP 1998-319631 19981110; KR 99044817 A KR

1998-37215 19980909; US 6248458 B1 US 1998-178515 19981026; KR 2001021486 A Div ex KR 1998-37215 19980909, KR 2000-71522 20001129; US 2001031380 A1

Cont of US 1998-178515 19981026, US 2001-848282 20010504; KR 313912 B Div ex KR 1998-37215 19980909, KR 2000-71522 20001129; KR 320455 B KR 1998-37215 19980909 US 2001031380 A1 Cont of US 6248458; KR 313912 B Previous Publ. KR 2001021486; KR 320455 B Previous Publ. KR 99044817 PRAI KR 1998-18193 19980520; KR 1997-60534 19971117; KR 2000-71522 20001129 IC ICM C09K011-00; H01L033-00; H01L051-20; H05B033-12; H05B033-22 ICS C09K011-06 AΒ 917216 A UPAB: 19990714 NOVELTY - An organic electroluminescent (EL) device including at least one organic EL layer between first and second electrodes comprises a layer formed of at least one porphyrinic compound. USE - As an organic light-emitting diode in a flat-panel display device. ADVANTAGE - The devices have a long lifetime, e.g. 100 hours to greater than 2,000 hours, and high efficiency. The porphyrin enhances adhesion of the organic/metal interface, making contact with the second electrode through open spaces in the thin, metal-containing layer, and extends the lifetime. Both the lifetime and the electron-injecting capability are increased by using a mixed layer of the porphyrin and metal-containing materials between the lightemitting layer and the cathode. FS CPI EPI FΑ AB; GI; DCN MC CPI: L03-C04; L03-D01D EPI: U12-A01A1X; U14-J; X26-J L37 ANSWER 35 OF 73 INSPEC COPYRIGHT 2003 FIZ KARLSRUHE 1999:6351073 INSPEC AN DN B1999-10-4260D-072 ΤI Improvement of metal-organic interface by insertion of mono-layer size insulating layer in organic EL device. ΑU Kurosaka, Y.; Tada, N.; Ohmori, Y.; Yoshino, K. (Dept. of Electron. Eng., Osaka Univ., Japan) Synthetic Metals (June 1999) vol.102, no.1-3, p.1101-2. 2 refs. SO Doc. No.: S0379-6779(98)01386-1 Published by: Elsevier Price: CCCC 0379-6779/99/\$20.00 CODEN: SYMEDZ ISSN: 0379-6779 SICI: 0379-6779(199906)102:1/3L.1101:IMOI;1-S Conference: International Conference on Science and Technology of Synthetic Metals. Montpellier, France, 12-18 July 1998 DTConference Article; Journal TC Practical; Experimental CY Switzerland LA English AΒ Insertion of mono-layer size insulating layer into the cathode/organic and anode/organic layer has been investigated in an organic EL device, which consists of 8-hydroxyquinoline aluminum (Alq,) as an emissive layer and diamine (TPD) as a hole transporting layer. The emission characteristics have been improved by insertion of mono-layer size of Al203 between electrode and organic layers, and the dependence of layer thickness of Al2O3 has been investigated.

B4260D Light emitting diodes; B4220 Luminescent materials; B2810

Dielectric materials and properties

- CT ALUMINA; ELECTROLUMINESCENCE; INSULATING THIN FILMS;
 LIGHT EMITTING DIODES; MONOLAYERS; ORGANIC COMPOUNDS;
 ORGANOMETALLIC COMPOUNDS
- ST metal-organic interface; mono-layer size insulating layer; organic EL device; cathode/organic layer; anode/organic layer; 8-hydroxyquinoline aluminum; emissive layer; diamine; hole transporting layer; emission characteristics; Al203; layer thickness
- CHI Al203 int, Al2 int, Al int, O3 int, O int, Al203 bin, Al2 bin, Al bin, O3 bin, O bin
- ET Al*O; Al2O3; Al cp; cp; O cp; Al2O; Al; O
- L37 ANSWER 36 OF 73 HCAPLUS COPYRIGHT 2003 ACS DUPLICATE 4
- AN 1999:141732 HCAPLUS
- DN 130:303742
- TI Organic-inorganic multilayer structures: a novel route to highly efficient organic light-emitting diodes
- AU Riess, Walter; Riel, Heike; Seidler, Paul F.; Vestweber, Horst
- CS Zurich Research Laboratory, IBM Research Division, Rueschlikon, CH-8803, Switz.
- SO Synthetic Metals (1999), 99(3), 213-218 CODEN: SYMEDZ; ISSN: 0379-6779
- PB Elsevier Science S.A.
- DT Journal
- LA English
- CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
 Section cross-reference(s): 76
- AB A novel device structure for org. lightemitting diodes (OLEDs) is described, which consists in the most general case of an alternating sequence of thin inorg. and org. layers sandwiched between 2 electrodes
 - . Compared to conventional OLEDs, these **devices** have a significantly enhanced current flow, increased brightness, and higher luminous efficiency at a given voltage. These improvements in performance can be attributed to increased and more balanced charge-carrier injection as well as charge-carrier confinement effects, which together lead to higher radiative recombination probability.
- ST LED org inorg multilayer carrier injection radiative recombination; ITO LED multilayer carrier injection radiative recombination; calcium LED multilayer carrier injection radiative recombination; magnesium LED multilayer carrier injection radiative recombination; silver LED multilayer carrier injection radiative recombination; silica LED multilayer carrier injection radiative recombination; alumina LED multilayer carrier injection radiative recombination; calcia LED multilayer carrier injection radiative recombination; rubrene LED multilayer carrier injection radiative recombination; hydroxyquinoline aluminum LED multilayer carrier injection radiative recombination; copper phthalocyanine LED multilayer carrier injection radiative recombination; lithium fluoride LED multilayer carrier injection radiative recombination; current voltage LED multilayer carrier injection radiative recombination
- IT Electric current carriers
 - (injection; org.-inorg. multilayer structures with novel route to highly efficient org. light-emitting diodes by radiative recombination enhancement through carrier injection and confinement)
- IT Electric current-potential relationship

```
Electroluminescent devices
     Radiative recombination
        (org.-inorg. multilayer structures with novel route to highly
        efficient org. light-emitting diodes by radiative
        recombination enhancement through carrier injection and confinement)
ΙT
     50926-11-9, ITO
     RL: DEV (Device component use); USES (Uses)
        (anode; org.-inorg. multilayer structures with novel route to
        highly efficient org. light-emitting diodes by
        radiative recombination enhancement through carrier injection and
        confinement)
IT
     147-14-8, Copper phthalocyanine
     RL: DEV (Device component use); USES (Uses)
        (buffer-injection layer; org.-inorg. multilayer
        structures with novel route to highly efficient org. light-
        emitting diodes by radiative recombination enhancement through
        carrier injection and confinement)
ΙT
     7439-95-4, Magnesium, uses 7440-70-2, Calcium, uses
     RL: DEV (Device component use); USES (Uses)
        (cathode; org.-inorg. multilayer structures with novel route
        to highly efficient org. light-emitting diodes by
        radiative recombination enhancement through carrier injection and
        confinement)
IT
     7440-22-4, Silver, uses
     RL: DEV (Device component use); MOA (Modifier or additive use);
     USES (Uses)
        (cathode; org.-inorg. multilayer structures with novel route
        to highly efficient org. light-emitting diodes by
        radiative recombination enhancement through carrier injection and
        confinement)
     1305-78-8, Calcia, uses 7631-86-9, Silica, uses
ΙT
     7789-24-4, Lithium fluoride, uses
     RL: DEV (Device component use); MOA (Modifier or additive use);
     USES (Uses)
        (inorg. ultrathin film; org.-inorg. multilayer structures
        with novel route to highly efficient org. light-
        emitting diodes by radiative recombination enhancement through
        carrier injection and confinement)
     2085-33-8, Hydroxyquinoline aluminum
IT
                                            123847-85-8
     RL: DEV (Device component use); USES (Uses)
        (org.-inorg. multilayer structures with novel route to highly
        efficient org. light-emitting diodes by radiative
        recombination enhancement through carrier injection and confinement)
    517-51-1, Rubrene 1344-28-1, Alumina, uses
IT
                                                  7429-90-5,
    Aluminum, uses
    RL: DEV (Device component use); MOA (Modifier or additive use);
    USES (Uses)
        (org.-inorg. multilayer structures with novel route to highly
       efficient org. light-emitting diodes by radiative
       recombination enhancement through carrier injection and confinement)
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- (22) Shirota, Y; Appl Phys Lett 1994, V65, P807 HCAPLUS
- (23) Tang, C; 1996 SID Int'l Symp Digest of Technical Papers 1996, V27, P181
- (24) Tang, C; Appl Phys Lett 1987, V51, P913 HCAPLUS
- (25) Tang, C; Information Display 1996, V12, P16
- (26) Vanslyke, S; Appl Phys Lett 1996, V69, P2160 HCAPLUS
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- L37 ANSWER 37 OF 73 INSPEC COPYRIGHT 2003 IEE
- AN 1999:6305721 INSPEC DN B1999-09-4260D-008
- TI Organic light-emitting diodes and their stability.
- AU Zhou Xiang; Hou Xiaoyuan (Surface Phys. Lab., Fudan Univ., Shanghai, China)
- SO Wuli (April 1999) vol.28, no.4, p.201-6. 16 refs. Published by: Science Press CODEN: WULIAL ISSN: 0379-4148 SICI: 0379-4148(199904)28:4L.201:OLED;1-W
- DT Journal
- TC Experimental
- CY China
- LA Chinese
- AB Organic light-emitting diodes (OLEDs) are ready for commercialization. However their stability is still a key issue. A brief review is given of OLEDs and their stability, focusing mainly on the degradation process, effects of water and oxygen, inter-reactions between electrodes and organic materials, and the thermal stability of the organic materials.
- CC B4260D Light emitting diodes
- CT LIGHT EMITTING DIODES; ORGANIC COMPOUNDS; THERMAL STABILITY
- organic light-emitting diodes; OLED; commercialization; degradation process; water effects; O effects; electrodes-organic materials interreactions; thermal stability; organic LED; H2O; O2
- CHI H2O bin, H2 bin, H bin, O bin; O2 el, O el
- ET 0; H*O; H2O; H cp; cp; O cp; O2; H

L37 ANSWER 38 OF 73 COMPENDEX COPYRIGHT 2003 EEI AN 1999(49):3518 COMPENDEX ΤI Improvement of metal-organic interface by insertion of mono-layer size insulating layer in organic EL device. AU Kurosaka, Y. (Osaka Univ, Osaka, Jpn); Tada, N.; Ohmori, Y.; Yoshino, K. MT Proceedings of the 1999 International Conference on Science and Technology of Synthetic Metals (ICSM-98). Ministere de l'Education Nationale; Universite de Montpellier II; Conseil MO Regional du Languedoc-Roussillon; District de Montpellier; et al. MLMontpellier 12 Jul 1998-18 Jul 1998 MD SO Synthetic Metals v 102 n 1-3 pt 2 Jun 1999.p 1101-1102 CODEN: SYMEDZ ISSN: 0379-6779 PY 1999 MN 55266 DTJournal TC Experimental LA English AB Insertion of mono-layer size insulating layer into the cathode/organic and anode/organic layer has been investigated in organic EL device, which consists of 8-hydroxyquinoline aluminum (Alq3) as an emissive layer and diamine (TPD) as a hole transporting layer. The emission characteristics have been improved by insertion of mono-layer size of Al203 between electrode and organic layers, and the dependence of layer thickness of Al203 has been investigated. (Author abstract) 2 Refs. CC 714.2 Semiconductor Devices and Integrated Circuits; 804.1 Organic Components; 701.1 Electricity: Basic Concepts and Phenomena; 741.1 Light. Optics; 931.2 Physical Properties of Gases, Liquids and Solids; 712.1.2 Compound Semiconducting Materials CT *Light emitting diodes; Alumina; Interfaces (materials); Light sources; Morphology; Current voltage characteristics; Semiconducting indium compounds; Aluminum compounds; Amines; Electroluminescence ST Hydroxyquinoline aluminum; Diamine; Hole transporting layer ETAl*O; Al2O3; Al cp; cp; O cp ANSWER 39 OF 73 HCAPLUS COPYRIGHT 2003 ACS L37 AN 1998:176122 HCAPLUS DN 128:237067 ΤI Electrode deposition for organic light-emitting devices Pichler, Karl; Devine, Peter IN Cambridge Display Technology Limited, UK; Pichler, Karl; Devine, Peter PΑ SO PCT Int. Appl., 50 pp. CODEN: PIXXD2 DTPatent LΑ English IC ICM H01L033-00 ICS H05B033-26; H05B033-10 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties) Section cross-reference(s): 75, 76 FAN.CNT 2

APPLICATION NO.

WO 1997-GB2395

DATE

19970904

KIND DATE

19980312

A1

PATENT NO.

WO 9810473

PΙ

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W: CN, GB, JP, US
         RW: AT, BE, CH, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE
                       A1
     GB 2332094
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                                                             19970904
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                       A1
                            19991006
                                            EP 1997-939049
                                                             19970904
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             IE, FI
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PRAI GB 1996-18473
                       Α
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                       \mathbf{A}
                            19960904
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                       Α
                            19960904
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                       Α
                            19970612
     WO 1997-GB2395
                       W
                            19970904
     US 1999-254302
                       A1.
                            19991223
AB
     Org. light-emitting devices having at least
     one layer of light-emitting org.
     material arranged between first and second electrodes
     are described in which .gtoreq.1 of first and second electrodes
     has a multilayer structure, each layer of the
     multilayer structure being a d.c. magnetron sputtered
     layer. Org. light-emitting devices
     having two or more layers of light-emitting
     org. material arranged between first and second
     electrodes are also described in which an uppermost layer
     of the org. material being more resistant to sputter deposition than an
     underlying layer of the org. material, and the electrode formed
     over the uppermost layer of org. material being a sputtered
     layer. Methods for making the structures are also described.
ST
     sputtered electrode org light emitting device
IT
     Electric contacts
      Electrodes
      Electroluminescent devices
     Semiconductor device fabrication
     Sputtering
        (org. light-emitting devices with
        sputtered electrodes)
IT
     Osmium alloy
     Rhenium alloy
     Tellurium alloy
     antimony alloy
    arsenic alloy
    barium alloy
    calcium alloy
    carbon alloy
    cerium alloy
    cesium allov
    cobalt alloy
    copper alloy
    europium allov
    germanium alloy
    gold alloy
    indium alloy
    lead alloy
    lithium alloy
    magnesium alloy
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manganese alloy

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nickel alloy
     palladium alloy
     platinum alloy
     potassium alloy
     rubidium alloy
     ruthenium alloy
     samarium alloy
     selenium alloy
     silicon alloy
     silver alloy
     sodium alloy
     strontium alloy
     terbium alloy
     tin alloy
     titanium allov
     tungsten alloy
     ytterbium alloy
     zinc alloy
     zirconium alloy
     RL: DEV (Device component use); PEP (Physical, engineering or
     chemical process); PROC (Process); USES (Uses)
        (org. light-emitting devices with
        sputtered electrodes)
IT
     1314-13-2, Zinc oxide, uses
                                   1332-29-2, Tin oxide
                                                        7429-90-5,
                     7440-02-0, Nickel, uses 7440-02-0D, Nickel,
     Aluminum, uses
     intermetallic compds., uses 7440-04-2, Osmium, uses
     Osmium, intermetallic compds., uses
                                         7440-05-3, Palladium, uses
     7440-05-3D, Palladium, intermetallic compds., uses
                                                         7440-06-4, Platinum,
     uses
            7440-06-4D, Platinum, intermetallic compds., uses 7440-15-5,
     Rhenium, uses
                     7440-15-5D, Rhenium, intermetallic compds., uses
     7440-18-8, Ruthenium, uses 7440-18-8D, Ruthenium, intermetallic compds.,
            7440-22-4, Silver, uses
                                      7440-22-4D, Silver, intermetallic
     compds., uses
                    7440-38-2, Arsenic, uses
                                                7440-38-2D, Arsenic,
     intermetallic compds., uses
                                   7440-44-0, Carbon, uses
                                                            7440-48-4, Cobalt,
            7440-48-4D, Cobalt, intermetallic compds., uses 7440-56-4
     , Germanium, uses 7440-56-4D, Germanium, intermetallic compds.,
            7440-57-5, Gold, uses
                                  7440-57-5D, Gold, intermetallic compds.,
     uses 7782-49-2, Selenium, uses 7782-49-2D, Selenium,
     intermetallic compds., uses 11099-19-7 11099-22-2
                                                             13494-80-9,
     Tellurium, uses
                     13494-80-9D, Tellurium, intermetallic compds., uses
     50926-11-9, Indium tin oxide 96638-49-2, Poly(phenylene vinylene)
     138184-36-8, Poly(2-methoxy,5-(2'-ethyl-hexyloxy)-p-phenylene vinylene)
     RL: DEV (Device component use); PEP (Physical, engineering or
     chemical process); PROC (Process); USES (Uses)
        (org. light-emitting devices with
        sputtered electrodes)
RE.CNT
             THERE ARE 7 CITED REFERENCES AVAILABLE FOR THIS RECORD
(1) Bulovic, V; APPLIED PHYSICS LETTERS 1997, V70(22), P2954 HCAPLUS
(2) Eastman Kodak Co; EP 0468437 A 1992 HCAPLUS
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(4) Holmes, A; WO 9403031 A 1994 HCAPLUS
(5) Sumitomo Chemical Co; EP 0443861 A 1991 HCAPLUS
(6) Suzuki, H; APPLIED PHYSICS LETTERS 1996, V68(16), P2276 HCAPLUS
(7) Yoshikawa, M; US 5006915 A 1991 HCAPLUS
L37 ANSWER 40 OF 73 HCAPLUS COPYRIGHT 2003 ACS
AN
    1998:365162 HCAPLUS
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DN
     129:60379
     Organic electroluminescent device
ΤI
     Hosokawa, Chishio; Matsuura, Masahide; Tokailin, Hiroshi
ΙN
     Idemitsu Kosan Company Limited, Japan
PΑ
SO
     Eur. Pat. Appl., 26 pp.
     CODEN: EPXXDW
DT
     Patent
     English
LA
IC
     ICM H05B033-28
     73-11 (Optical, Electron, and Mass Spectroscopy and Other Related
     Properties)
     Section cross-reference(s): 76
FAN.CNT 1
     PATENT NO.
                     KIND DATE
                                          APPLICATION NO.
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                     A2
     EP 845924
                           19980603
                                          EP 1997-120854
                                                           19971127
                     A3 19990120
     EP 845924
         R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT,
             IE, SI, LT, LV, FI, RO
     JP 10162959
                      A2
                           19980619
                                          JP 1996-319567
                                                           19961129
     JP 10294182
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     EP 1119221
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                           20010725
                                          EP 2001-109489
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     EP 1119221
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                           20020918
         R: BE, CH, DE, FR, GB, IT, LI, NL, SE
     EP 1119222
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                                                           19971127
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                     A3
                           20020918
         R: BE, CH, DE, FR, GB, IT, LI, NL, SE
     US 6284393 B1
                           20010904
                                       US 1997-980345
                                                           19971128
PRAI JP 1996-319567
                     Α
                           19961129
     JP 1997-101570
                           19970418
                    Α
     EP 1997-120854
                     А3
                           19971127
AΒ
     Org. electroluminescent devices comprising a pos.
     electrode, a neg. electrode, and an org. layer including an
     org. light-emitting layer as
     sandwiched between the two electrodes are
     described in which the neg. electrode comprises an electron injection
     electrode layer and an amorphous transparent conductive film,
     and the electron injection electrode layer is adjacent to the
     org. layer, or in which the neg. electrode compriseds an
     electron injection electrode layer, a transparent conductive
     film, and a thin metal film having a specific resistance of not larger
     than 1 \times 10-5 .OMEGA..cntdot.cm, as laminated in that order with the
     electron injection electrode layer being adjacent to the org.
     layer, and a thin transparent film is formed outside the neg.
     electrode. Preferably, the transparent conductive film is amorphous.
     devices have a neg. electrode with low resistance and high
     transparency, and have high luminous efficiency and good durability (wet
     heat resistance). Light can be taken out through the side of the neg.
     electrode of the devices.
ST
     org electroluminescent device neg electrode structure
IT
    Transparent films
        (elec. conductive, films; electroluminescent device
       neg. electrode structures)
IT
    Anodes
      Electroluminescent devices
        (electroluminescent device neg. electrode
       structures)
IT
    Electric conductors
```

(films, transparent, films; electroluminescent device neg. electrode structures) IT Electric contacts Electrodes (transparent; electroluminescent device neg. electrode structures) ΙT 147-14-8, Copper phthalocyanine 2085-33-8, Tris(8hydroxyquinolinato) aluminum 7439-95-4, Magnesium, uses Silver, uses 13463-67-7, Titania, uses 50926-11-9, Indium tin 65181-78-4, N,N'-Diphenyl-N,N'-bis(3-methylphenyl)-1,1'-biphenyl-4,4'-diamine 117944-65-7, Indium zinc oxide RL: DEV (Device component use); USES (Uses) (electroluminescent device neg. electrode structures) L37 ANSWER 41 OF 73 INSPEC COPYRIGHT 2003 IEE 1998:5914562 INSPEC DN B9806-7260-113 See-through, multi-pixel organic emissive display. AU Yap, D. (HRL, Malibu, CA, USA) SO Electronics Letters (30 April 1998) vol.34, no.9, p.915-16. 3 refs. Published by: IEE Price: CCCC 0013-5194/98/\$10.00 CODEN: ELLEAK ISSN: 0013-5194 SICI: 0013-5194(19980430)34:9L.915:TMPO;1-R Journal DTTC Experimental CY United Kingdom LA English AΒ A see-through multi-pixel emissive display has been demonstrated. The 8*12 pixel display, fabricated on a glass substrate, has two partially transparent electrodes that sandwich multi-layer, thin film organic materials. The fabrication approach is based on common integrated circuit processing techniques and can be extended to form active matrix addressed displays on silicon substrates. B7260 Display technology and systems; B4260 Electroluminescent devices CC ELECTROLUMINESCENT DISPLAYS; ORGANIC COMPOUNDS; TRANSPARENCY CTST see-through multi-pixel emissive display; glass substrate; partially transparent electrode; sandwich multilayer thin film organic material; fabrication; integrated circuit processing; active matrix addressing; silicon substrate; 8 pixel; 12 pixel picture size 8.0E+00 pixel; picture size 1.2E+01 pixel L37 ANSWER 42 OF 73 HCAPLUS COPYRIGHT 2003 ACS DUPLICATE 5 AN1999:37535 HCAPLUS DN 130:188741 TΙ Improvement of electrode-organic interface by insertion of monolayer size Al203 layer in organic EL device Ohmori, Yutaka; Kurosaka, Yoshitaka; Tada, Norio; Sawatani, Takumi; Ueta, ΑU Hiroshi; Yoshino, Katsumi Department of Electronic Engineering, Osaka University, Suita, 565-0871, CS Japan SO Molecular Crystals and Liquid Crystals Science and Technology, Section A: Molecular Crystals and Liquid Crystals (1998), 322, 263-270 CODEN: MCLCE9; ISSN: 1058-725X PΒ Gordon & Breach Science Publishers

73-5 (Optical, Electron, and Mass Spectroscopy and Other Related

DT

LА

СC

Journal

English

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Properties)
      Section cross-reference(s): 76
      Improvement of electrode/org. interface was studied in org.
 AΒ
      electroluminescent diode which consists of 8-hydroxyquinoline
      aluminum and diamine deriv. An aluminum oxide (Al203) monolayer inserted
     between electrode and org. interface was
      studied. Emission efficiency was increased by inserting monolayer size of
     Al203 between anode and org. layer and between cathode and org.
      layer. The mechanism of improvement in emission efficiency is
      discussed.
      alumina nanometer thin film electroluminescence org
 ST
     light emitting diode; electrode coating aluminum oxide
     electroluminescent device
     Electrodes
         (alumina coating; electroluminescent device with
         alumina thin films between electrodes and
         org. layers)
IT
     Electric current-potential relationship
     Interface
     Ultrathin films
         (electroluminescent device with alumina thin films
        between electrodes and org. layers
ΙT
     Electroluminescent devices
         (with alumina thin films between electrodes and
        org. layers)
ΙT
     50926-11-9, Indium tin oxide
     RL: DEV (Device component use); USES (Uses)
         (anode; electroluminescent device with alumina thin
        films between electrodes and org.
        layers)
ΙT
     7429-90-5, Aluminum, processes
     RL: PEP (Physical, engineering or chemical process); PROC (Process)
         (deposition onto ITO and org. layers of
        electroluminescent device, and oxidn. to form thin
        alumina layer)
ΙT
     1344-28-1, Aluminum oxide (Al2O3), uses
     RL: DEV (Device component use); USES (Uses)
        (electroluminescent device with alumina thin films
        between electrodes and org. layers
     2085-33-8, Tris(8-quinolinolato)aluminum
ΙT
     RL: DEV (Device component use); PRP (Properties); USES (Uses)
        (emissive layer; electroluminescent device
        with alumina thin films between electrodes and
        org. layers)
     65181-78-4, [1,1'-Biphenyl]-4,4'-diamine, N,N'-bis(3-methylphenyl)-N,N'-
ΙT
     diphenyl-
     RL: DEV (Device component use); PRP (Properties); USES (Uses)
        (hole transport; electroluminescent device with
        alumina thin films between electrodes and
        org. layers)
     7440-22-4, Silver, uses
IT
     RL: DEV (Device component use); USES (Uses)
        (magnesium cathode contg.; electroluminescent device
        with alumina thin films between electrodes and
        org. layers)
ΙT
    7439-95-4, Magnesium, uses
```

RL: DEV (Device component use); USES (Uses) (silver contg. cathode; electroluminescent device with alumina thin films between electrodes and org. layers)

RE.CNT 13 THERE ARE 13 CITED REFERENCES AVAILABLE FOR THIS RECORD RE

- (1) Adachi, C; Appl Phys Lett 1990, V56, P799 HCAPLUS
- (2) Burrows, P; IEEE Trans Electron Devices 1997, VED-44, P1188
- (3) Hung, L; Appl Phys Lett 1997, V70, P152 HCAPLUS
- (4) Ishii, H; IEEE Trans Electron Devices 1997, V44, P1295 HCAPLUS
- (5) Kido, J; Science 1995, V267, P1332 HCAPLUS
- (6) Li, F; Appl Phys Lett 1997, V70, P1233 HCAPLUS
- (7) Ohmori, Y; Appl Phys Lett 1993, V62, P3250 HCAPLUS
- (8) Ohmori, Y; Jpn J Appl Phys 1991, V30, PL1938
- (9) Sheats, J; Science 1997, V277, P191 HCAPLUS
- (10) Shen, Z; Science 1997, V276, P2009 HCAPLUS
- (11) Tang, C; Appl Phys Lett 1987, V51, P913 HCAPLUS
- (12) Van Slyke, S; Appl Phys Lett 1996, V69, P2160 HCAPLUS
- (13) Wu, C; Appl Phys Lett 1996, V69, P3117 HCAPLUS
- L37 ANSWER 43 OF 73 JICST-EPlus COPYRIGHT 2003 JST
- AN 980780997 JICST-EPlus
- TI Improvement of Emission Characteristic of Organic EL Device by Insertion of Aluminume Oxide Thin Film.
- AU KUROSAKA YOSHITAKA; TADA NORIO; OMORI YUTAKA; YOSHINO KATSUMI
- CS Osaka Univ., Grad. Sch.
- Denshi Joho Tsushin Gakkai Gijutsu Kenkyu Hokoku (IEIC Technical Report (Institute of Electronics, Information and Communication Enginners)), (1998) vol. 98, no. 168 (OME98 57-69), pp. 63-68. Journal Code: S0532B (Fig. 3, Ref. 13)
- CY Japan
- DT Journal; Article
- LA Japanese
- STA New
- AB Improvement of electrode/organic interface has been studied in organic electroluminescent diodes which consist of 8-hydroxyquinoline aluminum (Alq3) and diamine derivative (TPD). Mono-layer size aluminum oxide(Al2O3) layer was inserted between organic layer and electrode (anode or cathode). Improvement of emission efficiency has been observed in the diode with mono-layer size Al2O3 layer inserted between electrode and organic layer. The mechanism of increase in emission efficiency has been discussed. (author abst.)
- CC NC03082G; BK14070L (621.383:535.35; 539.23:547)
- electroluminescence; aluminum complex; aluminum oxide; organic material; ultrathin film; quantum efficiency; buffer layer; nitrogen heterocyclic compound; hydroxy compound; polynuclear aromatic compound; aromatic amine
- BT luminescence; aluminum compound; 3B group element compound; metal complex; complex(compound); coordination compound; compound(chemical); 3B group element complex; metal oxide; oxide; chalcogenide; oxygen group element compound; oxygen compound; material; thin film; membrane and film; efficiency; layer; heterocyclic compound; aromatic compound; amine
- L37 ANSWER 44 OF 73 JICST-EPlus COPYRIGHT 2003 JST
- AN 990013399 JICST-EPlus
- TI Improvement of Electrode-Organic Interface in Organic EL Device.
- AU OMORI YUTAKA; KUROSAKA YOSHITAKA; SAWATANI TAKUMI; YOSHINO KATSUMI

- CS Osaka Univ. Denki Gakkai Yuden, Zetsuen Zairyo Kenkyukai Shiryo, (1998) vol. DEI-98, SO no. 52-63, pp. 57-62. Journal Code: Z0908B CY LΑ Japanese STA New Improvement of electrode/organic interface has been studied in organic electroluminescent diodes which consist of 8-hydroxyquinoline aluminum (Alq3) and diamine derivative (TPD). Mono-layer size aluminum oxide (Al203) layer was inserted between organic layer and electrode (anode or cathode). Improvement of emission efficiency has been observed in the diode with mono-layer size Al203 layer inserted between electrode and organic layer. The mechanism of increase in emission efficiency has been discussed. The emissive site has been investigated by inserting mono-layer size marker layer into the emissive layer. The efficient emissive site has been also discussed. (author abst.) L37 ANSWER 45 OF 73 COMPENDEX COPYRIGHT 2003 EEI AN 1999(3):3949 COMPENDEX Organic light years ahead. ΤI AU Sealy, Cordelia SO European Semiconductor Design Production Assembly v 20 n 10 Oct 1998.p 19-20 CODEN: EUSEEK ISSN: 0265-6027 PY 1998 DTJournal TC General Review LA English AB The display market still promises a great future and one technology, organic light emitting diode (OLED) displays, is bringing new life to this market. OLED consists of several thin semiconducting and electroluminescent organic layers sandwiched between electrodes. When a voltage is applied to metal electrode contacts, light is emitted, the color depending on the type of electroluminescent organic material used. The organic layers are in OLEDs are transparent to their own luminescence and most of the visible spectrum. OLED displays can employ a vertical staked pixel architecture. Each device in the stack emits light of its characteristic color through the adjacent organic layers, contacts and glass substrates. 714.2 Semiconductor Devices and Integrated Circuits; 712.1.2 Compound CC Semiconducting Materials; 701.1 Electricity: Basic Concepts and Phenomena; 741 Light, Optics and Optical Devices; 714.1 Electron Tubes; 812.3 Glass CT*Light emitting diodes; Electroluminescence; Substrates; Electrodes; Optical glass; Evaporation; Thermoanalysis; Sputter deposition; Semiconductor growth; Semiconducting organic compounds ST Organic light emitting diode (OLED) displays; Active matrix liquid crystal displays (AMLCD) L37 ANSWER 46 OF 73 COMPENDEX COPYRIGHT 2003 EEI 1998(51):2530 COMPENDEX AN
- TI Science and technology of organic EL displays.

- ΑU Hudson, A.J. (Sharp Lab of Europe Ltd, Oxford, Engl)
- MT Proceedings of the 1998 International Symposium on Information Theory, CLEO/EUROPE'98.
- MLGlasgow, Scotland

- MD 14 Sep 1998-18 Sep 1998
- SO Conference on Lasers and Electro-Optics Europe Technical Digest 1998.IEEE, Piscataway, NJ, USA.p 17 CME1 CODEN: 85PNA9
- PY 1998
- MN 49092
- DT Conference Article
- TC General Review
- LA English
- AΒ For display applications, organic EL offers the possibility of efficient, low voltage, multicolour operation coupled with low production costs and robust design. Typical organic EL devices, as shown in figure 1, consist of several organic layers deposited between two electrodes. The organic layers are usually deposited by vacuum sublimation or polymer spinning. On applying a voltage across the device oppositely charged carriers are injected from the two electrodes and are transported to the recombination zone. The carriers then recombine forming excited molecular states which decay radiatively giving out emission with a characteristic spectrum. Recent progress in this field will be summarised and the performance of current devices compared to that of established displays (principally LCDs and inorganic EL) as well as other new technologies (plasma, FEDs etc.). The key areas which are currently limiting performance, such as the injection efficiency, carrier transport and carrier recombination efficiency, will be discussed. Although the best devices already have lifetimes in excess of 10,000 hours, lifetime is still an issue and will also be considered. (Author abstract) 2 Refs.
- CC 741.3 Optical Devices and Systems; 741.1 Light. Optics; 802.3 Chemical Operations; 801.4.1 Electrochemistry; 633.1 Vacuum Applications; 931.3 Atomic and Molecular Physics
- *Luminescent devices; Deposition; Electronic density of states; Electrochemical electrodes; Sublimation; Vacuum applications; Charge transfer; Carrier concentration; Molecular dynamics; Luminescence of organic solids
- ST Vacuum sublimation; Injection efficiency; Carrier transport; Carrier recombination
- L37 ANSWER 47 OF 73 HCAPLUS COPYRIGHT 2003 ACS
- AN 1997:684586 HCAPLUS
- DN 127:352842
- TI Electroluminescent device
- IN Ilegems, Marc; Schar, Michel; Zuppiroli, Libero
- PA Ecole Polytechnique Federale de Lausanne, Switz.; Ilegems, Marc; Schar, Michel; Zuppiroli, Libero
- SO PCT Int. Appl., 28 pp.
 - CODEN: PIXXD2
- DT Patent
- LA French
- IC ICM H05B033-28
- CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
 - Section cross-reference(s): 36, 76
- FAN.CNT 1

| | PATENT NO. | KIND | DATE | APPLICATION NO. | DATE |
|----|------------|------|----------|-----------------|----------|
| | | | | | |
| ΡI | WO 9738558 | A1 | 19971016 | WO 1997-CH133 | 19970402 |

w: UP, US

RW: AT, BE, CH, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE

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EP 891686
                       A1
                             19990120
                                           EP 1997-908105
                                                             19970402
     EP 891686
                       В1
                             19991006
         R: BE, CH, DE, ES, FR, GB, IT, LI, NL, SE, FI
     JP 2000508112 T2
                            20000627
                                          JP 1997-535714
                                                             19970402
                       B1
     US 6208074
                            20010327
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                                                             19981006
PRAI CH 1996-863
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                            19960403
     WO 1997-CH133
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                            19970402
AΒ
     An electroluminescent device is described which
     includes a layer of electroluminescent org.
     semiconductor material between a 1st transparent
     electrode made of an n-type semiconductor material selected from
     nitrides and inorg. oxides, and a 2nd electrode.
     electroluminescent device org semiconductor
     transparent electrode; LED org semiconductor transparent electrode;
     nitride semiconductor electrode transparent LED org; oxide semiconductor
     electrode transparent LED org; polymer org semiconductor LED transparent
     electrode; current voltage LED semiconductor org polymer
TΤ
     Electrodes
        (LED electron injector; electroluminescent device
        including electroluminescent org. semiconductor material and
        transparent semiconductor electrode)
IT
     Nitrides
     Oxides (inorganic), uses
     RL: DEV (Device component use); USES (Uses)
        (LED semiconductor transparent electrode; electroluminescent
        device including electroluminescent org.
        semiconductor material and transparent semiconductor electrode)
     Semiconductor materials
IT
        (LED; electroluminescent device including
        electroluminescent org. semiconductor material and transparent
        semiconductor electrode)
IT
     Electric current-potential relationship
       Electroluminescent devices
        (electroluminescent device including
        electroluminescent org. semiconductor material and transparent
        semiconductor electrode)
IT
     Polymers, uses
     RL: DEV (Device component use); USES (Uses)
        (electroluminescent device including
        electroluminescent org. semiconductor material and transparent
        semiconductor electrode)
IT
     1344-28-1, Alumina, uses
                              2085-33-8, Hydroxyquinoline aluminum
     13463-67-7D, Titania, derivs.
                                     15082-28-7, Butyl-PBD
     18282-10-5, Tin dioxide 25617-97-4, Gallium nitride
                                                             50926-11-9, ITO
     65181-78-4, [1,1'-Biphenyl]-4,4'-diamine, N,N'-bis(3-methylphenyl)-N,N'-
     diphenyl-
               150144-97-1
                              174141-60-7, Aluminum gallium indium nitride
     181024-45-3, Gallium indium nitride
     RL: DEV (Device component use); USES (Uses)
        (electroluminescent device including
       electroluminescent org. semiconductor material and transparent
       semiconductor electrode)
IT
    7429-90-5, Aluminum, uses 7439-93-2, Lithium, uses
    7440-21-3, Silicon, uses 7440-31-5, Tin, uses
    7440-46-2, Cesium, uses 7440-70-2, Calcium, uses
    Sulfur, uses 7782-49-2, Selenium, uses 12385-13-6, Hydrogen
    atom, uses 13463-67-7D, Titania, nonstoichiometric
                                                         13494-80-9.
    Tellurium, uses
    RL: DEV (Device component use); MOA (Modifier or additive use);
```

```
USES (Uses)
         (electroluminescent device including
         electroluminescent org. semiconductor material and transparent
         semiconductor electrode)
 IT
     7440-59-7, Helium, uses
                               7727-37-9, Nitrogen, uses
     RL: NUU (Other use, unclassified); USES (Uses)
         (electroluminescent device including
         electroluminescent org. semiconductor material and transparent
         semiconductor electrode)
 ΙT
     7664-41-7, Ammonia, processes
                                    17108-85-9, Gallium monochloride
     RL: PEP (Physical, engineering or chemical process); RCT (Reactant); PROC
      (Process); RACT (Reactant or reagent)
         (electroluminescent device including
        electroluminescent org. semiconductor material and transparent
        semiconductor electrode)
L37 ANSWER 48 OF 73 WPIX
                              (C) 2003 THOMSON DERWENT
     1998-073961 [07]
AN
                        WPIX
     1997-251039 [23]
CR
DNN N1998-059332
                        DNC C1998-024734
     Electroluminescent element used in illumination for display,
     signal light generation element - has mixolimnion provided between
     cathode electrode and organic EL
     layer.
DC
     E12 L03 U11 U14 X26
IN
     KANEKO, N; SHIRASAKI, T; YAMADA, H
PA
     (CASK) CASIO COMPUTER CO LTD
CYC
PΙ
     JP 09312196
                   A 19971202 (199807) *
                                               gę
                                                     H05B033-14
                                                                      <--
     US 5834894 A 19981110 (199901)
                                                     H01J001-62
ADT
     JP 09312196 A JP 1996-150473 19960523; US 5834894 A US 1996-711869
     19960912
PRAI JP 1996-150473
                    19960523; JP 1995-260997
                                                 19950914
     ICM H01J001-62; H05B033-14
IC
     ICS H01L033-00
AΒ
     JP 09312196 A UPAB: 19990107
     The element has an organic EL layer
     interposed between cathode and anode electrodes
     (17,13). The cathode electrode is made of silver which is considered as
     first material. Between the cathode electrode and a transportation
     layer mixolimnion (16) made of Alq3 and Mg which is
     considered as second material, is provided.
          The work function of the second material is smaller than that of the
     first material. A hole transportation layer (14) is formed between
     the anode electrode and the organic EL
     layer.
          ADVANTAGE - Inhibits deterioration of cathode electrode. Increases
     light emitting brightness and light
     emitting luminous efficiency.
     Dwg.1/7
     CPI EPI
FS
FΆ
     AB; GI
MC
     CPI: L03-C04
     EPI: U14-J02; X26-J
L37 ANSWER 49 OF 73 INSPEC COPYRIGHT 2003 IEE
                                                       DUPLICATE 6
                             DN A9803-7340N-004; B9802-2530D-005
AN
     1998:5787839 INSPEC
     Controlling charge injection in organic electronic devices using
ΤI
```

self-assembled monolayers.

- AU Campbell, I.H.; Kress, J.D.; Martin, R.L.; Smith, D.L. (Los Alamos Nat. Lab., NM, USA); Barashkov, N.N.; Ferraris, J.P.
- SO Applied Physics Letters (15 Dec. 1997) vol.71, no.24, p.3528-30. 17 refs. Doc. No.: S0003-6951(97)01150-9 Published by: AIP

Price: CCCC 0003-6951/97/71(24)/3528/3/\$10.00 .

CODEN: APPLAB ISSN: 0003-6951

SICI: 0003-6951(19971215)71:24L.3528:CCIO;1-R

- DT Journal
- TC Practical; Experimental
- CY United States
- LA English
- We demonstrate control and improvement of charge injection in organic electronic devices by utilizing self-assembled monolayers (SAMs) to manipulate the Schottky energy barrier between a metal electrode and the organic electronic material. Hole injection from Cu electrodes into the electroluminescent conjugated polymer poly[2-methoxy,5-(2'-ethyl-hexyloxy)-1,4-phenylene vinylene] was varied by using two conjugated-thiol based SAMs. The chemically modified electrodes were incorporated in organic diode structures and changes in the metal/polymer Schottky energy barriers and current-voltage characteristics were measured. Decreasing (increasing) the Schottky energy barrier improves (degrades) charge injection into the polymer.
- A7340N Metal-nonmetal contacts; A7330 Surface double layers, Schottky barriers, and work functions; B2530D Semiconductor-metal interfaces; B4260 Electroluminescent devices; B2560S Other field effect devices
- CT CHARGE-COUPLED DEVICES; **ELECTROLUMINESCENT** DEVICES; MONOLAYERS; POLYMERS; SCHOTTKY BARRIERS
- charge injection control; organic electronic devices; selfassembled monolayers; Schottky energy barrier; metal electrode; hole injection; electroluminescent conjugated polymer; poly[2-methoxy,5-(2'-ethyl-hexyloxy)-1,4-phenylene vinylene]; chemically modified electrodes; current-voltage characteristics; Cu
- CHI Cu int, Cu el
- ET Cu
- L37 ANSWER 50 OF 73 HCAPLUS COPYRIGHT 2003 ACS DUPLICATE 7
- AN 1997:601922 HCAPLUS
- DN 127:337274
- TI Electron spectroscopy studies of interface formation between metal electrodes and luminescent organic materials
- AU Park, Y.; Choong, V.-E.; Hsieh, B. R.; Tang, C. W.; Wehrmeister, T.; Mullen, K.; Gao, Y.
- CS Department of Physics and Astronomy, University of Rochester, Rochester, NY, 14627, USA
- SO Journal of Vacuum Science & Technology, A: Vacuum, Surfaces, and Films (1997), 15(5), 2574-2578 CODEN: JVTAD6; ISSN: 0734-2101
- PB American Institute of Physics
- DT Journal
- LA English
- CC 66-4 (Surface Chemistry and Colloids)
- AB Using x-ray and UPS (XPS and UPS), we have studied the formation of metal/org. interfaces in org. electroluminescent devices

 Oligo(p-phenylenevinylenes) (OPV) and tris-(8-hydroxyquinoline)aluminum (Alq3) were used as the org. materials and Ca was used as the metallic

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layer. Interfaces are formed differently by depositing org. layer on Ca and Ca on org. substrate. For Ca/OPV, UPS revealed a clear evidence for interface state formation upon Ca deposition. evolution of XPS core level peak as a function of Ca layer thickness was consistent with the energy level bending picture. and UPS spectra for OPV/Ca as a function of org. layer thickness also confirmed the energy level bending. The data obtained allowed us to deduce the energy level diagram near the interface. Similar data for Alq3/Ca indicated that no electron injection barrier exists at this interface if the Alq3 optical band gap in the literature was used for estg. the energy position of the lowest unoccupied state. interface metal electrode luminescent org material Electroluminescent devices Energy level Interface Spectroscopy X-ray photoelectron spectra (electron spectroscopy studies of interface formation between metal electrodes and luminescent org. materials) 7440-70-2, Calcium, miscellaneous RL: MSC (Miscellaneous) (electron spectroscopy studies of interface formation between metal electrodes and luminescent org. materials) 2085-33-8, Tris-(8-hydroxyquinoline) aluminum 26009-24-5, Poly(p-Phenylenevinylene) RL: PEP (Physical, engineering or chemical process); PRP (Properties); PROC (Process) (electron spectroscopy studies of interface formation between metal **electrodes** and luminescent **org**. materials) L37 ANSWER 51 OF 73 JAPIO COPYRIGHT 2003 JPO 1996-055974 JAPIO FULL CONTACT IMAGE SENSOR AND ORGANIC ELECTROLUMINESCENCE ELEMENT NAKATANI KENJI; NANBA NORIYOSHI; ARAI MICHIO TDK CORP JP 08055974 A 19960227 Heisei JP 1994-190778 (JP06190778 Heisei) 19940812 PRAI JP 1994-190778 19940812 PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1996 ICM H01L027-146 C09K011-06; H05B033-14 PURPOSE: To provide a full contact image sensor and an organic electroluminescence of simple and compact constitution without complicated processing in a base part. CONSTITUTION: In a full contact image sensor which irradiates a sensing object with light from a light source and enters its reflection light into a photosensor directly, a photosensor 6 and a light source 5 are arranged flush and a thin plate 3 is arranged on the photosensor and the light source. The light source is constituted of an organic EL element of a thin film, for example. Furthermore, the organic EL element is provided with an insulation film between an electrode and an organic compound layer to enable selection of a light emitting part. COPYRIGHT: (C) 1996, JPO

L37 ANSWER 52 OF 73 INSPEC COPYRIGHT 2003 IEE DN A9621-7860F-005 AN 1996:5385381 INSPEC

- Organic electroluminescence and applications.

 AU Dubois, C.; Le Barny, P.; Bouche, C.M.; Berdague, P.; Facoetti, H.; Robin, P. (Lab. Central de Recherches, Thomson-CSF, Domaine de Corbeville,
- Photoactive Organic Materials. Science and Applications. Proceedings of the NATO Advanced Research Workshop
 Editor(s): Kajzar, F.; Agranovich, V.M.; Lee, C.Y.-C.
 Dordrecht, Netherlands: Kluwer Academic Publishers, 1996. p.313-23 of x+572 pp. 9 refs.
 Conference: Avignon, France, 25-30 June 1995

Sponsor(s): NATO ISBN: 0-7923-3973-8

Conference Article

- TC General Review; Experimental
- CY Netherlands

France)

LA English

DT

- AB When an organic conjugated material is sandwiched between two suitable electrodes and a voltage is applied, visible light is emitted. Such an emission produced by the action of an electrical current is called electroluminescence (EL). In this paper we present a brief history, the main characteristics and materials of organic luminescence. We present also some performances of materials and the problems to be solved for the future development.
- CC A7860F Electroluminescence; A0130R Reviews and tutorial papers; resource letters
- CT **ELECTROLUMINESCENCE**; ORGANIC COMPOUNDS; REVIEWS
- ST organic electroluminescence; organic conjugated material; electrodes; voltage; visible light; electrical current; electroluminescence; organic luminescence
- L37 ANSWER 53 OF 73 INSPEC COPYRIGHT 2003 IEE DUPLICATE 8
 AN 1997:5617127 INSPEC DN A9715-7860F-003; B9708-4260D-007
- TI Organic electroluminescence: materials and devices.
- AU Kalinowski, J. (Istituto di Fotochimica e Radiazioni di Alta Energia, CNR, Bologna, Italy)
- Proceedings of the SPIE The International Society for Optical Engineering (1996) vol.2780, p.293-303. 43 refs.

 Published by: SPIE-Int. Soc. Opt. Eng
 Price: CCCC 0 8194 2166 9/96/\$6.00

 CODEN: PSISDG ISSN: 0277-786X

 SICI: 0277-786X(1996)2780L.293:OEMD;1-Z

 Conference: Metal/Nonmetal Microsystems: Physics, Technology, and Applications. Polanica Zdroj, Poland, 11-14 Sept 1995

 Sponsor(s): SPIE; State Committee for Sci. Res.; Tech. Univ. Wroclaw; et
- DT Conference Article; Journal
- TC General Review; Practical; Experimental
- CY United States
- LA English

al

AB Electroluminescence (EL) in organics is a phenomenon of both fundamental and practical interest. Defined as direct conversion of electricity into light, it incorporates many physical processes which are not yet fully understood. Considered originally as an organic analogue of the Destriau effect, the high-field or intrinsic EL found previously in inorganic phosphors remains still obscure since narrow bands in organic solids rule out electron acceleration to energies allowing impact generation of electronic excited states. Therefore. The search for

wide-band organic materials is a challenge to design and to fabricate organic intrinsic EL devices. The recombination radiation following the excess charge carrier injection into a luminescent material stands for injection EL. This type of EL is commonly accepted as a basis for the emission of light from organic materials sandwiched between metal electrodes. In this review, some consequences of the band width and energy level positions in low-molecular weight organic materials and polymers are discussed. Fundamental concepts are illustrated using the notions of recombination (tau rec) and transit (tau T) times of charge carriers. Injection-controlled (tau rec> tau T) and volume-controlled (tau rec< tau T) injection EL modes are distinguished in organic light emitting-diodes (LEDs). Two routes to fabricate spectrally tunable organic LEDs are discussed: (a) building multilayer devices with various materials as chromophores (emitters) and (b) employing single-layer conjugated polymer matrix, or molecularly-doped non-conjugated polymers with appropriate selection of the optically active component important factors affecting the recombination routes and production of emitting states as is demonstrated on EL from single organic crystals. Using photoinjecting contacts instead of dark-injecting electrodes allows to design a unique light transducer combining an organic EL diode with the photosensitive film. Selected examples of organic LEDs and light transducers are presented. Some directions for further work are given.

- CC A7860F Electroluminescence; A7135 Excitons and related phenomena; A0130R Reviews and tutorial papers; resource letters; B4260D Light emitting diodes; B4220 Luminescent materials
- CT ELECTROLUMINESCENCE; ELECTRON TRAPS; ELECTRON-HOLE RECOMBINATION; EXCITONS; LIGHT EMITTING DIODES; OPTICAL POLYMERS; ORGANIC COMPOUNDS; POLYMER BLENDS; REVIEWS
- organic electroluminescence; organics; high-field EL;
 narrow bands; impact generation; electronic excited states; wide-band
 organic materials; organic intrinsic EL devices; recombination
 radiation; excess charge carrier injection; luminescent material; organic
 materials; metal electrodes; review; band width; energy level positions;
 low-molecular weight organic materials; polymers; injection EL
 modes; organic light emitting-diodes; LED; spectrally
 tunable organic LEDs
- L37 ANSWER 54 OF 73 INSPEC COPYRIGHT 2003 IEE
- AN 1997:5693308 INSPEC DN A9720-7860F-005; B9710-4220-027
- TI **Electroluminescence** in organic solids: phenomenon and applications.
- AU Kalinowski, J. (FRAE, CNR, Bologna, Italy)
- SO Molecular Physics Reports (1996) vol.14, p.103-18. 43 refs.
 Published by: Osrodek Wydawnictw Naukowych
 CODEN: MPREFZ
 Conference: 10th National Conference Molecular Crystals. Kiekrz, Poland,
 3-6 Sept 1995
- DT Conference Article; Journal
- TC Application; General Review; Practical; Experimental
- CY Poland
- LA English
- AB Electroluminescence (EL) in organic solids is a phenomenon of both fundamental and practical interest. Defined as direct conversion of electricity into light it incorporates many physical processes which are not yet fully understood. Considered originally as an organic analogue of the Destriau effect that is high-field or intrinsic

EL found previously in inorganic phosphors, remains still obscure since narrow bands in organic solids rule out electron acceleration to energies allowing impact generation of electronic excited states. Therefore, the search for wide-band organic materials is a challenge to design and to fabricate organic intrinsic EL devices. The recombination radiation following the excess charge carrier injection into a luminescent material stands for injection EL. This type of EL is commonly accepted as a basis for the emission of light from organic materials sandwiched between metal electrodes. In this review, some consequences of the band width and energy level positions in low-molecular weight organic materials and polymers are discussed. Fundamental concepts are illustrated using the notions of recombination (tau rec) and transit (tau T) times of charge carriers. Injection-controlled (tau rec< tau T) and volume-controlled (tau rec< tau T) injection EL modes are distinguished in organic light-emitting-diodes (LEDs). Two routes to fabricate spectrally tunable organic LEDs are discussed: (a) building multilayer devices with various materials as chromophores (emitters) and (b) employing single-layer conjugated polymer systems with different main-chain molecular structures and blending luminescent polymers into the host polymer matrix, or molecularly-doped non-conjugated polymers with appropriate selection of the optically active component. Charge carrier trapping and excitonic interactions are important factors affecting the recombination routes and production of emitting states as is demonstrated on EL from single organic crystals. Using photoinjecting contacts instead of dark-injecting electrodes allows to design a unique light transducer combining an organic EL diode with the photosensitive film. Selected examples of organic LEDs and light transducers are presented. Some directions for further work are given. A7860F Electroluminescence; A4270F Other optical materials; A0130R Reviews and tutorial papers; resource letters; A7135 Excitons and related phenomena; B4220 Luminescent materials; B4260D Light emitting diodes ELECTROLUMINESCENCE; ELECTRON-HOLE RECOMBINATION; EXCITONS; LIGHT EMITTING DIODES; OPTICAL POLYMERS; ORGANIC

- ST electroluminescence; organic solids; intrinsic EL;
 narrow bands; electron acceleration; impact generation; electronic excited
 states; wide-band organic materials; organic intrinsic EL devices
 ; recombination radiation; excess charge carrier injection; luminescent
 material; injection EL; metal electrodes; review; band width;
 energy level positions; low-molecular weight organic materials; polymers;
 recombination; transit times; excitons; light-emitting-diodes;
 conjugated polymers
- L37 ANSWER 55 OF 73 COMPENDEX COPYRIGHT 2003 EEI

COMPOUNDS; POLYMER BLENDS; REVIEWS

- AN 1996(9):1449 COMPENDEX
- TI Ultraviolet electroluminescence from an organic light emitting diode.
- AU Berggren, Magnus (Linkoping Univ, Linkoping, Sweden); Granstrom, Magnus; Inganas, Olle; Andersson, Mats
- SO Advanced Materials v 7 n 11 Nov 1995.p 900-903 CODEN: ADVMEW ISSN: 0935-9648
- PY 1995

CT

- DT Journal
- TC Experimental
- LA English
- AB Two organic layers are sandwiched between the electrodes. One layer consists of a blend of PBD

(2-(4-biphenyl)-5-(4-t-butylphenyl)-1,3,4-oxadiazole) and PTOPT (poly left bracket 3-(4-octylphenyl)-2,2 prime -bitiophene right bracket, the second of an evaporated layer of PBD only. Scanning force microscopy imaging and optical investigations indicate that phase separation exists. At the same time a fraction of the polymer is molecularly dispersed in the PBD phase. This composition results in the injection and recombination properties that lead to a light emitting diode with an emission maximum at 394nm. The highest measured external quantum efficiency in these devices is 0.1%. Since one part of the emission just below 394 nm is located in the visible region, the emission color is best described as violet.18 Refs.

- CC 741.1 Light. Optics; 714.2 Semiconductor Devices and Integrated Circuits; 815.1.1 Organic Polymers; 741.3 Optical Devices and Systems; 931.4 Quantum Theory; 701.1 Electricity: Basic Concepts and Phenomena
- *Electroluminescence; Current voltage characteristics; Organic
 polymers; Ultraviolet radiation; Luminescent devices; Photoluminescence;
 Imaging techniques; Quantum efficiency; Light emitting
 diodes; Light emission
- ST Ultraviolet electroluminescence; Low molecular weight compound; Wavelength
- L37 ANSWER 56 OF 73 JICST-EPlus COPYRIGHT 2003 JST
- AN 950524781 JICST-EPlus
- TI Polarization Characteristics of **EL** Output from Film Edge of **Organic EL** Device **Sandwiched** by Metal **Electrodes**.
- AU UEDA TAKASHI; HIRAMOTO MASAHIRO; YOKOYAMA MASAAKI
- CS Osaka Univ., Fac. of Eng.
- SO Nippon Kagakkai Koen Yokoshu, (1995) vol. 69th, no. 2, pp. 632. Journal Code: S0493A
 ISSN: 0285-7626
- CY Japan
- LA Japanese
- STA New
- AB Polarization characteristics of **EL** output from film edge of **organic EL** device **sandwiched** by metal **electrodes** were investigated. In the case of device having very thin organic layer, strongest **EL** intensity was observed for the **EL** light having the electric field perpendicular to organic film (TM mode), in spite of its severe waveguiding loss by the metal absorption. (author abst.)
- L37 ANSWER 57 OF 73 JICST-EPlus COPYRIGHT 2003 JST
- AN 950386846 JICST-EPlus
- TI Metal Electrodes for Organic Electroluminescent Devices.
- AU INABA RITSUO
- CS Matsushita Electr. Ind. Co., Ltd., Cent. Res. Lab.
- Denshi Joho Tsushin Gakkai Gijutsu Kenkyu Hokoku (IEIC Technical Report (Institute of Electronics, Information and Communication Enginners)), (1995) vol. 94, no. 535 (OME94 78-83), pp. 31-36. Journal Code: S0532B (Fig. 6)
- CY Japan
- DT Journal; Article
- LA Japanese
- STA New
- AB The decrease of the efficiency of the organic **electroluminesent** devises was examined for various metal electrodes. Work function of the metal electrodes, Mg, MgAg, Al, AlLi were measured and compare with the

amplitude of the electroluminescence. Work function at the metal surface rapidly increased after fabrication but at the surface between organic layer and metal electrode kept constant over 1000 central hours. (author abst.) CC NC03082G (621.383:535.35) photoelectric device; electroluminescence; organic semiconductor; electrode; magnesium; aluminum; electrode material; efficiency; work function; light emission; time course; aluminum base alloy; lithium base alloy; lifetime ВT solid state device; luminescence; semiconductor; organic conductor; conductor; object; alkaline earth metal; metallic element; element; third row element; 3B group element; electric material; material; function(mathematics); mapping(mathematics); potential; variation; light alloy; nonferrous alloy; alloy; metallic material L37 ANSWER 58 OF 73 JAPIO COPYRIGHT 2003 JPO AΝ 1994-188073 JAPTO ΤI ORGANIC FILM ELEMENT IN SHOJI TAKESHI; MORI YOSHIHIKO PA ASAHI CHEM IND CO LTD PΤ JP 06188073 A 19940708 Heisei ΑI JP 1993-195948 (JP05195948 Heisei) 19930806 PRAI JP 1992-216888 19920814 PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1994 SO IC ICM H05B033-22 C23C014-06; H01L031-04; H01L031-0344 ICA C09K011-06 PURPOSE: To reduce non-light emitting parts in a light emission surface, and improve light emission efficiency in an organic electroluminescent element having an organic layer between a positive electrode and a negative electrode by providing an island-like silver distribution layer between the organic layer and the negative electrode. CONSTITUTION: In an organic electroluminescent element having an organiclayer between electrodes comprising a positive electrode and a negative electrode, a silver distribution layer which is seen like an island by observation by a scan type electron microscope or a transmission type electron microscope is provided between the layer most on the negative electrode side and the negative electrode. The organic electroluminescent element emits light when holes charged from the positive electrode and electrons charged from the negative electrode are recombined with each other in a light emission layer, where charge of the electrons have effects of an interface condition because it is performed at the interface between the negative electrode and the organic layer. By providing the silver distribution layer at the interface between the negative electrode and the organic layer, tightness between the negative electrode and the organic layer is improved to form a new hierarchy at the interface. As a result, non-light emitting parts in the light emission surface can be reduced, thereby light emission efficiency can be improved regardless of what is used for material of the negative electrode. COPYRIGHT: (C) 1994, JPO&Japio

L37 ANSWER 59 OF 73 JAPIO COPYRIGHT 2003 JPO

1994-151062 AN JAPIO MANUFACTURE OF LIGHT EMITTING ELEMENT ΤI IN MIYASHITA SATORU PA SEIKO EPSON CORP PΙ JP 06151062 A 19940531 Heisei JP 1992-302646 (JP04302646 Heisei) 19921112 ΑI PRAI JP 1992-302646 19921112 PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1994 IC ICM **H05B033-26** ICS H01L033-00; H05B033-10 AB PURPOSE: To provide an organic light emitting layer between electrodes, laminate a dry film resist on an upper electrode layer, perform exposure, development with alkali aqueous solution, and etching, and provide a large capacity displayable electrode pattern. CONSTITUTION: An ITO, is evaporated on a glass base 11 followed by photographic etching to form a lower electrode pattern 12. An oxadiazole derivative is evaporated to form a positive hole injection layer 13, and anthracene is evaporated to form a light emitting layer 14, and an upper electrode layer 15 of In is superposed thereon. A dry film resist is treated in a determined way to form a resist layer 16. It is exposed through a photo-mask 17 and developed with 1% aqueous solution of sodium carbonate to pattern the resist layer 16. The IN is etched with aqueous solution of hydrochloric acid to provide the upper electrode 15. The positive hole injection layer 13 and the light emitting layer 14 are never affected nor deformed, and the light emitting characteristic uniform within a face can be provided. The time divided drive in line can be performed, and satisfactory display characteristic is exhibited. COPYRIGHT: (C) 1994, JPO& Japio L37 ANSWER 60 OF 73 JAPIO COPYRIGHT 2003 JPO AN 1993-251186 JAPIO TI LIGHT EMITTING ELEMENT AND MANUFACTURE THEREOF IN MIYASHITA SATORU PA SEIKO EPSON CORP JP 05251186 A 19930928 Heisei PΙ JP 1992-49891 (JP04049891 Heisei) 19920306 AΤ PRAI JP 1992-49891 19920306 SO PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1993 IC ICM **H05B033-26** H01L029-28; H01L033-00; H05B033-10 PURPOSE: To provide an organic light emitting element AB having an electrode pattern capable of displaying a large capacity, having a high initial yield and a high in-plane uniformity, and excellent in long-term reliability. CONSTITUTION: In a light emitting element having at least an organic light emitting layer 14 between electrodes, at least one of the electrodes is constituted of a high polymer layer 15 where conductive particles are dispersed. Application of a high polymer solution where conductive particles are dispersed by a printing method can provide a pattern, followed by fixing the aid of heat, thus manufacturing the light emitting element. Otherwise, application of a solution including conductive particles and high polymer molecules by a printing method can provide a pattern, followed by polymerization and fixing by heating or ultraviolet ray irradiation, thereby manufacturing the light emitting element.

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L37 ANSWER 61 OF 73 JAPIO COPYRIGHT 2003 JPO

AN 1992-206296 JAPIO

TI ORGANIC ELECTROLUMINESCENT ELEMENT

IN SANO KENJI; KAWADA YASUSHI; URANO TAEKO; MORI YASUSHI

PA TOSHIBA CORP

PI JP 04206296 A 19920728 Heisei

AI JP 1990-333035 (JP02333035 Heisei) 19901129

PRAI JP 1990-333035 19901129

SO PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1992

IC ICM H05B033-14

ICS C09K011-06; H01J029-20; H01L033-00

PURPOSE: To enable long life of EL element by providing an organic EL layer with a structural formula of Al(C<SB>9</SB>H<SB>6</SB>ON)<SB>3</SB>, containing a compound showing specified absorbing peaks in a far inflared radiation absorbing spectra. CONSTITUTION: On a glass base, ITO electrode 2, hall transport layer 3, EL layer 4 and Mg-Al electrode 5 are formed in suquence, and a power supply 6 is connected between the electrodes 2, 5. The organic EL layer 4 is provided with a structural formula of Al(C<SB>9</SB>H<SB>6</SB>ON)<SB>3</SB> and in a range 400-440cm<SP>-1</SP> in far inflared radiation absorbing spectra a compound showing two or more absorbing peas within an intencity ratio 1:1:5, i.e., isomer of alumioxyquinolinic complex is contained. It is thus possible to extend the service life of EL element. COPYRIGHT: (C)1992,JPO&Japio

L37 ANSWER 62 OF 73 JAPIO COPYRIGHT 2003 JPO

AN 1991-037293 JAPIO

TI ORGANIC ELECTROLUMINESCENT ELEMENT

IN TASHIRO MASASHI; MATAGA SHUNTARO; TAKAHASHI KAZUFUMI; SATO YOSHIHARU; MAEDA SHUICHI

PA MITSUBISHI KASEI CORP

PI JP 03037293 A 19910218 Heisei

AI JP 1989-172177 (JP01172177 Heisei) 19890704

PRAI JP 1989-172177 19890704

SO PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1991

IC ICM C09K011-06

ICS H01L033-00; H05B033-14

AB PURPOSE: To enable an organic electroluminescent element comprising a pair of electrodes each comprising at least two conductive layers and, disposed between said electrodes, an organic hole injection transportation layer and an organic light-emitting layer to emit light of improved luminance at a low voltage by incorporating a specific compound in the organic light-emitting layer.

CONSTITUTION: An organic electroluminescent element comprising a pair of electrodes each comprising two conductive layers and, disposed between said electrodes, an organic hole

injection transportation layer and an organic

light- emitting layer, wherein the

organic light-emitting layer

contains a compound represented by formula I [wherein A to D each represent a substituted or unsubstituted aromatic hydrocarbon group; X represents a substituted or unsubstituted nitrogen atom, a sulfur atom, an oxygen atom or a selenium atom; and Y represents a hydrogen atom, a cyano

group, an amide group, an ester group, an alkyl group, a carboxyl group, a substituted or unsubstituted aromatic hydrocarbon group or a substituted or unsubstituted aromatic heterocyclic group] (e.g. a compound represented by formula II).

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L37 ANSWER 63 OF 73 JAPIO COPYRIGHT 2003 JPO

AN 1991-037292 JAPIO

TI ORGANIC ELECTROLUMINESCENT ELEMENT

IN SAITO SHOGO; TSUTSUI TETSUO; ADACHI CHIHAYA; TASHIRO MASASHI; MATAGA SHUNTARO

PA MITSUBISHI KASEI CORP

PI JP 03037292 A 19910218 Heisei

AI JP 1989-172176 (JP01172176 Heisei) 19890704

PRAI JP 1989-172176 19890704

SO PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1991

IC ICM C09K011-06

ICS H01L033-00; H05B033-14

AB PURPOSE: To enable an organic electroluminescent element comprising a pair of electrodes each comprising at least two conductive layers and, disposed between the electrodes, an organic hole injection transportation layer and an

organic light-emitting layer to

emit light of improved luminance at a low voltage by incorporating a specific compound in the organic light -emitting layer.

CONSTITUTION: An organic electroluminescent element comprising a pair of electrodes each comprising two conductive layers and, disposed between the electrodes, an organic hole

injection transportation layer and an organic

light- emitting layer, wherein the

organic light-emitting layer

contains a compound represented by formula I [wherein A and B each represent a substituted or unsubstituted aromatic hydrocarbon group; X represents a substituted or unsubstituted nitrogen atom, a sulfur atom, an oxygen atom or a selenium atom; and Y represents a nitrogen atom or a substituted or unsubstituted carbon atom] (e.g. a compound represented by formula II).

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L37 ANSWER 64 OF 73 JAPIO COPYRIGHT 2003 JPO

AN 1990-251429 JAPIO

TI TRANSPARENT CONDUCTIVE FILM

IN WAKI HIROSHI; OHASHI YUTAKA; FUKUDA NOBUHIRO

PA MITSUI TOATSU CHEM INC

PI JP 02251429 A 19901009 Heisei

AI JP 1989-71795 (JP01071795 Heisei) 19890327

PRAI JP 1989-71795 19890327

SO PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1990

IC ICM B32B009-00

ICS H01B005-14; H01L033-00

ICA H05B033-28

AB PURPOSE: To obtain a transparent conductive film suitable for a high capacity light emitting element having flexibility by constituting the transparent conductive film formed on a polymer film of an oxide film based on indium oxide and containing tin oxide and antimony oxide in a specific amount with respect to indium oxide.

CONSTITUTION: A transparent film is obtained by forming an oxide film

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based on indium oxide and containing 2-25wt.% of tin oxide and antimony oxide on a polymer film in a membrane form and especially suitable for the substrate of an EL element. A light emitting element formed by setting the transparent conductive film to at least one electrode and providing an org. compound membrane laver between two opposed electrodes as a layer developing light emitting function has flexibility and can be prepared as a uniform membrane having large area and rich in mass productivity and advantageous from the aspect of cost. In the org. compound membrane layer, an org. compound having high light emitting quantum efficiency and a π electron system easy to receive external perturbation and easily excited is used suitably. COPYRIGHT: (C) 1990, JPO&Japio L37 ANSWER 65 OF 73 JAPIO COPYRIGHT 2003 JPO 1990-251428 **JAPIO** TRANSPARENT CONDUCTIVE FILM WAKI HIROSHI; OHASHI YUTAKA; FUKUDA NOBUHIRO MITSUI TOATSU CHEM INC JP 02251428 A 19901009 Heisei JP 1989-71794 (JP01071794 Heisei) 19890327 PRAI JP 1989-71794 19890327 PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1990 ICM B32B009-00 ICS H01B005-14; H01L033-00 ICA H05B033-28 PURPOSE: To obtain a transparent conductive film suitable for a high capacity light emitting element having flexibility by constituting the transparent conductive film formed on a polymer film of a composite oxide layer based on indium oxide and consisting of tin oxide or tin oxide and antimony oxide and a metal layer composed of gold, silver, palladium or a mixed alloy of them. CONSTITUTION: The transparent conductive film formed on a polymer film is composed of a laminated film consisting of a composite oxide layer based on indium oxide and composed of tin oxide or tin oxide and antimony oxide and a metal layer composed of gold, silver, palladium or a mixed alloy of them and especially suitable for the substrate of an EL element. A light emitting element formed by setting the transparent conductive film to at least one electrode and providing an org. compound membrane layer between two opposed electrodes as a layer developing light emitting function has flexibility and can be prepared as an uniform membrane having a large area and is rich in mass productivity and advantageous from the aspect of cost. COPYRIGHT: (C) 1990, JPO&Japio L37 ANSWER 66 OF 73 JAPIO COPYRIGHT 2003 JPO 1990-196475 **JAPIO** THIN FILM LIGHT-EMITTING ELEMENT OHASHI YUTAKA; WAKI HIROSHI; FUKUDA NOBUHIRO MITSUI TOATSU CHEM INC JP 02196475 A 19900803 Heisei JP 1989-13983 (JP01013983 Heisei) 19890125 PRAI JP 1989-13983 19890125 PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 1990 ICM H01L033-00 ICS H05B033-14

- PURPOSE: To obtain a highly bright and stable injection type thin film AB EL element by providing a light-emitting function manifestation layer which laminates an n-type inorganic semiconductor thin film layer and two organic compound thin film layers between two electrode layers in which at least one of them is transparent or translucent. CONSTITUTION: Two electrode layers 2 and 7 in which at least one of them is transparent or translucent are prepared and a lightemitting function manifestation layer 6 which laminates an n-type inorganic semiconductor thin film layer 3 and two organic compound thin film layers 4 and 5 is provided between two electrode layers. It is suitable that the foregoing two organic compound thin film layers 4 and 5 are composed of the layer 4 of a substance which is excited easily and the layer 5 of a substance having a large home mobility. For example, an ITO film and an SnO<SB>2</SB> film are formed on a glass substrate 1 and the first transparent electrode layer 2 is formed. An n-type a-Si:H film 3, aluminum oxine complex (Al(Ox) < SB > 3 < /SB >) thin film 4, and a large hole mobility layer 5 having a tetraphenyl thiophene skeleton are laminated after forming them on the electrode layer 2. A gold thin film is deposited on the above layer 5 and then the second electrode layer 7 is formed. COPYRIGHT: (C) 1990, JPO& Japio
- L37 ANSWER 67 OF 73 INSPEC COPYRIGHT 2003 IEE
- AN 1987:2961088 INSPEC DN A87113289
- TI Electroluminescence in thin films of organic dyes.
- AU Hayashi, S.; Era, M.; Etoh, H.; Tsutsui, T.; Saito, S.; Wang, T.T.; Matsuoka, S.
- SO Engineering Sciences Reports, Kyushu University (June 1987) vol.8, no.2, p.181-8. 26 refs.

 CODEN: SRKHEK ISSN: 0388-1717
- DT Journal
- TC Experimental
- CY Japan
- LA Japanese
- AB Electroluminescence (EL) in three types of organic thin films, amorphous pyrazoline films prepared by vacuum vapor deposition, cyanine dye multilayers prepared by the Langmuir-Blodgett method and crystalline perylene films by vacuum vapor deposition, were investigated. The organic thin films were sandwiched between an electron-injection electrode (Al or In) and a hole-injection electrode (Au, indium-tin-oxide, CuI, or poly(3-methylthiophene) film). EL was confirmed to originate from recombination of injected holes and electrons. The poly(3-methylthiophene) electrode was found to be the most excellent for hole injection. By use of this electrode, the threshold voltage for emission markedly lowered. Because the rate of carrier recombination was determined by the efficiency of electron injection, the improvement of an electron-injection electrode brought about a large increase of EL efficiency. In, which possesses low work function, was found to be favorable for an electron-injection electrode.
- CC 'A7860F Electroluminescence
- CT ELECTROLUMINESCENCE; ELECTRON-HOLE RECOMBINATION;
 LANGMUIR-BLODGETT FILMS; LUMINESCENCE OF ORGANIC SOLIDS; ORGANIC
 COMPOUNDS; THIN FILMS; VACUUM DEPOSITED COATINGS
- ST emission threshold voltage; electroluminescence; thin films; organic dyes; amorphous pyrazoline films; cyanine dye multilayers; perylene films; recombination; injected holes; electrons; carrier

recombination

- ET Al; In; Au; Cu*I; CuI; Cu cp; cp; I cp
- L37 ANSWER 68 OF 73 COMPENDEX COPYRIGHT 2003 EEI
- AN 1987(11):186489 COMPENDEX
- TI **ELECTROLUMINESCENCE** IN AMORPHOUS FILMS OF 1,3,5-TRIARYL-2-PYRAZOLINES.
- AU Hayashi, S. (AT&T Bell Lab, Murray Hill, NJ, USA); Wang, T.T.; Uchida, Y.; Saito, S.
- MT Extended Abstracts Fall Meeting (168th Society Meeting), The Electrochemical Society.
- MO Electrochemical Soc, Pennington, NJ, USA
- ML Las Vegas, NV, USA
- MD 13 Oct 1985-18 Oct 1985
- SO Electrochemical Society Extended Abstracts v 85-2. Publ by Electrochemical Soc, Pennington, NJ, USA p 593
 CODEN: ESABB6 ISSN: 0160-4619
- PY 1985
- MN 09038
- DT Conference Article
- LA English
- AB Compounds of 1,3,5-triaryl-2-pyrazolines are known to be carrier transport materials which fluoresce and exhibit a stable glassy state at room temperature. We have detected, for the first time, a noticeable amount of ac-induced electroluminescence (EL) in amorphous films (ca.about 1 to 3 mu m thick) which were prepared by vacuum depositing these compounds onto glass substrates coated with a transparent electrode (Indium-Tin-Oxide, ITO). The results suggest that the electroluminescence behavior of the systems might have originated in the bulk of pyrazoline films and not at the interfaces between the electrodes and the organic materials. (Edited author abstract) 3 refs.
- CC 804 Chemical Products; 701 Electricity & Magnetism; 741 Optics & Optical Devices
- CT *ORGANIC COMPOUNDS: Thin Films; FILMS: Amorphous;

ELECTROLUMINESCENCE: Measurements

- ST CARRIER TRANSPORT MATERIALS; TRANSPARENT ELECTRODE; PYRAZOLINE; EXTENDED ABSTRACT
- L37 ANSWER 69 OF 73 JAPIO COPYRIGHT 2003 JPO
- AN 2002-110359 JAPIO
- TI ORGANIC ELECTROLUMINESCENT ELEMENT
- IN YONEYAMA HIROTO; OKUDA DAISUKE; HIROSE HIDEKAZU; SEKI MIEKO; MASHITA KIYOKAZU; AGATA TAKESHI; SATO KATSUHIRO
- PA FUJI XEROX CO LTD
- PI JP 2002110359 A 20020412 Heisei
- AI JP 2000-303664 (JP2000303664 Heisei) 20001003
- PRAI JP 2000-303664 20001003
- SO PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 2002
- IC ICM H05B033-14
 - ICS H01L051-00; H05B033-22
- AB PROBLEM TO BE SOLVED: To provide an organic **electroluminescent** element that is easy to manufacture and has a sufficient luminance and excellent durability.

SOLUTION: In the organic electroluminescence element in which

one or plural organic compound layers are interposed

between a pair of electrodes made of a positive

electrode and a negative electrode, of which one is at least transparent

or semi-transparent, at least one layer of the organic compound layers contains one or more kind of a charge transfer polymer made of a repeating unit that contains as a partial structure at least one kind selected from the structure as expressed in Formula (I-1) and (I-2). In the formulae, each of Arl-Ar6 expresses independently a substituted or unsubstituted aryl group, each of R1-R3 expresses independently hydrogen atom, an alkyl group or the like, and each of X1 and X2 expresses independently a substituted or unsubstituted bivalent aromatic group, T expresses a bivalent straight chain hydrocarbon group or the like having a carbon number of 1 to 6, and k expresses 0 or 1, and each of m and n express independently an integer of 1 or more. COPYRIGHT: (C) 2002, JPO

- L37 ANSWER 70 OF 73 JAPIO COPYRIGHT 2003 JPO
- AN 2002-075654 JAPIO
- TI ORGANIC ELECTROLUMINESCENT ELEMENT
- IN HIROSE HIDEKAZU; OKUDA DAISUKE; YONEYAMA HIROTO; SEKI MIEKO; MASHITA KIYOKAZU; AGATA TAKESHI; SATO KATSUHIRO
- PA FUJI XEROX CO LTD
- PI JP 2002075654 A 20020315 Heisei
- AI JP 2000-256801 (JP2000256801 Heisei) 20000828
- PRAI JP 2000-256801 20000828
- SO PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 2002
- IC ICM H05B033-22
 - ICS C08G065-34; C09K011-06; H01L051-00; H05B033-14
- AB PROBLEM TO BE SOLVED: To provide an organic electroluminescent element which uses charge transporting polymer having good stability, preservation stability, solubility, and compatibility at emitting of light, has high luminescence intensity, brings out a stable performance even after repeated use, and can be easily manufactured. SOLUTION: In an organic electroluminescent element with one or more organic compound layers pinched between a pair of electrodes consisting of an anode and a cathode at least one of which is transparent or translucent, at least one

least one of which is transparent or translucent, at least one layer from the organic compound layers includes one or more kinds of charge transporting polyethers consisting of repeated units as a partial structure selected at least one kind from

repeated units as a partial structure selected at least one kind from structures expressed in formulae (I-1) and (I-2). In the formulae, Ar expresses a substituted or non-substituted univalent polynuclear aromatic ring or the like having 3 to 10 aromatic ring numbers, X expresses a substituted or non-substituted bivalent aromatic group, T expresses a bivalent straight-chain hydrocarbon group or the like having 1 to 6 carbon numbers, m expresses integers of 1 to 3 and k expresses 0 or 1. COPYRIGHT: (C) 2002, JPO

- L37 ANSWER 71 OF 73 JAPIO COPYRIGHT 2003 JPO
- AN 2001-257076 JAPIO
- TI ORGANIC EL ELEMENT
- IN KIDO JUNJI; EBISAWA AKIRA
- PA TDK CORP
 - KIDO JUNJI
- PI JP 2001257076 A 20010921 Heisei
- AI JP 2000-68363 (JP2000068363 Heisei) 20000313
- PRAI JP 2000-68363 20000313
- SO PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 2001
- IC ICM H05B033-14
 - ICS C09K011-06; H01L033-00; H05B033-22
- AB PROBLEM TO BE SOLVED: To realize an organic EL element which

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enables to achieve reliability of thermal stability and the like and high efficiency in the high brightness region at the same time by doping a triplet luminous material in an organic host material, particularly, in a non-conjugated unsaturated polymer. SOLUTION: The organic EL element comprises a hole injecting electrode, an electron injecting electrode and a luminous layer composed of an organic host material and a dopant disposed between these electrodes. The above organic material is made of a non-conjugated unsaturated polymer material and the above dopant is made of an organic metal complex capable of phosphorescence from a triplet state and contains at least a metal ion belonging to the VII family of the Mendeleyev periodic table. COPYRIGHT: (C) 2001, JPO L37 ANSWER 72 OF 73 JAPIO COPYRIGHT 2003 JPO 2001-244073 JAPIO ORGANIC FILM LUMINESCENT DISPLAY TERAO YUTAKA; SHIRAISHI YOTARO FUJI ELECTRIC CO LTD JP 2001244073 A 20010907 Heisei JP 2000-55488 (JP2000055488 Heisei) 20000301 PRAI JP 2000-55488 20000301 PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 2001 ICM **H05B033-10** ICS B23K026-00; **H01L021-302**; **H05B033-12**; H05B033-14; H05B033-22 B23K101:36 PROBLEM TO BE SOLVED: To provide an excellent organic film luminescent display easy to pattern the upper electrode in a desired shape without damaging the elements in laser beam machining and easy to manufacture with good productivity at a low cost. SOLUTION: This display is provided with a substrate, a lower electrode formed on the substrate, an organic electroluminescent medium layer including at least a light emitting layer formed on the lower electrode, and an upper electrode formed on the organic electroluminescent medium layer, and uses the overlapped area of the lower electrode, the organic electroluminescent medium layer and the upper electrode as a light emitting element respectively. The upper electrode and the organic electroluminescent medium layer are patterned in a desired shape by laser beam machining. A vapor deposited layer having a melting point lower than the upper electrode is provided at least in the laser beam machined portion between the lower electrode and the organic electroluminescent medium layer. COPYRIGHT: (C) 2001, JPO ANSWER 73 OF 73 JAPIO COPYRIGHT 2003 JPO 2001-076882 JAPIO ORGANIC EL ELEMENT, ITS MANUFACTURE AND ITS DISPLAY DEVICE TANAKA HARUO; MORIMOTO MITSURU ROHM CO LTD JP 2001076882 A 20010323 Heisei JP 1999-249954 (JP11249954 Heisei) 19990903 PRAI JP 1999-249954 19990903

PATENT ABSTRACTS OF JAPAN (CD-ROM), Unexamined Applications, Vol. 2001

ICM H05B033-26

ICS G09G003-20; G09G003-30; **H01L031-12**; **H05B033-08**; **H05B033-14**

PROBLEM TO BE SOLVED: To provide an organic EL element improving in current efficiency while forming both electrodes with transparent electrodes without giving damage to an organic layer due to temperature and having too large charge implanting barriers between the electrode and the organic layer, and a display device superior in display property using the organic EL element with both transparent faces for monitoring its light to be fedback on one side. SOLUTION: This organic EL element has a first light transmissive electrode 2 on a substrate 1 and an organic layer 7 with at least a luminescent layer 4 on the first electrode 2. A second light transmissive electrode 9 is provided on the organic layer 7 and at least the second electrode 9 is formed of indium oxide. A display device has a light feedback circuit provided on the side of the substrate 1 for driving the organic \mathbf{EL} element 10 with a light emitted from the organic EL element 10. COPYRIGHT: (C) 2001, JPO